

Miniaturization effects of solar cells: Microsystems Enabled Photovoltaics

Jose Luis Cruz-Campa, Ph.D.

January 21, 2015

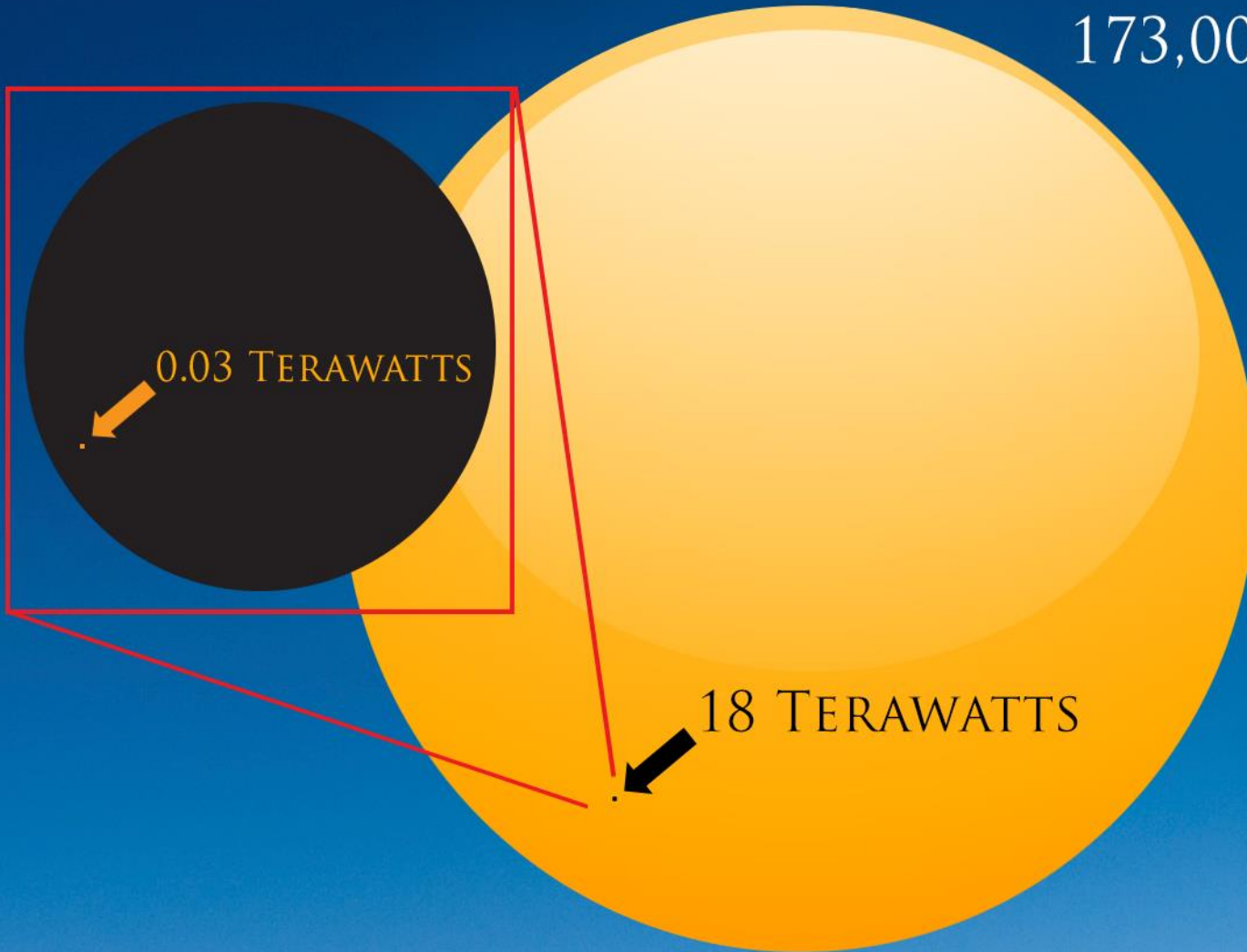
Outline

1. Better materials in Thin film cells
2. Flexible crystalline silicon cells
3. Compact concentrators

173,000 TERA WATTS

0.03 TERA WATTS

18 TERA WATTS





Four Solar technologies



Illumination
Passive heating



Active heating



Solar-thermal



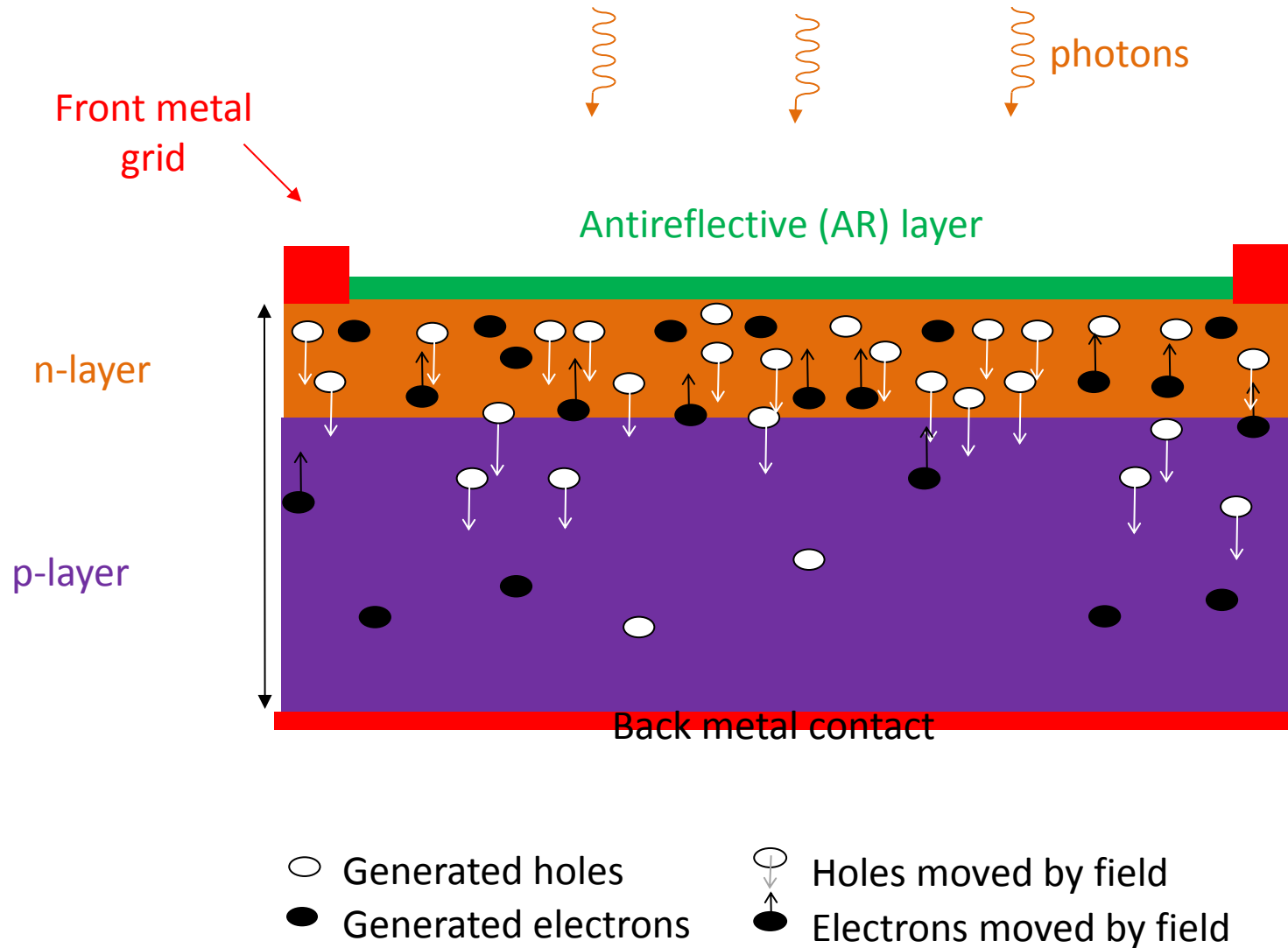
Photovoltaics (PV)

Advantages

Applications



How does a PV cell work?



Three types of PV

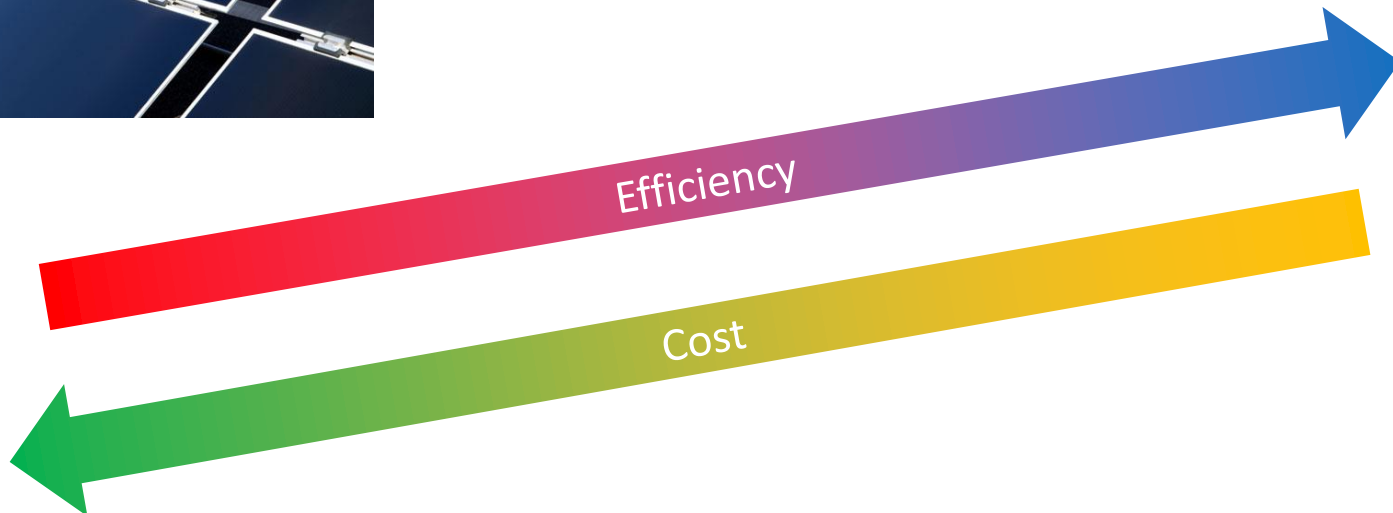
Concentrated PV



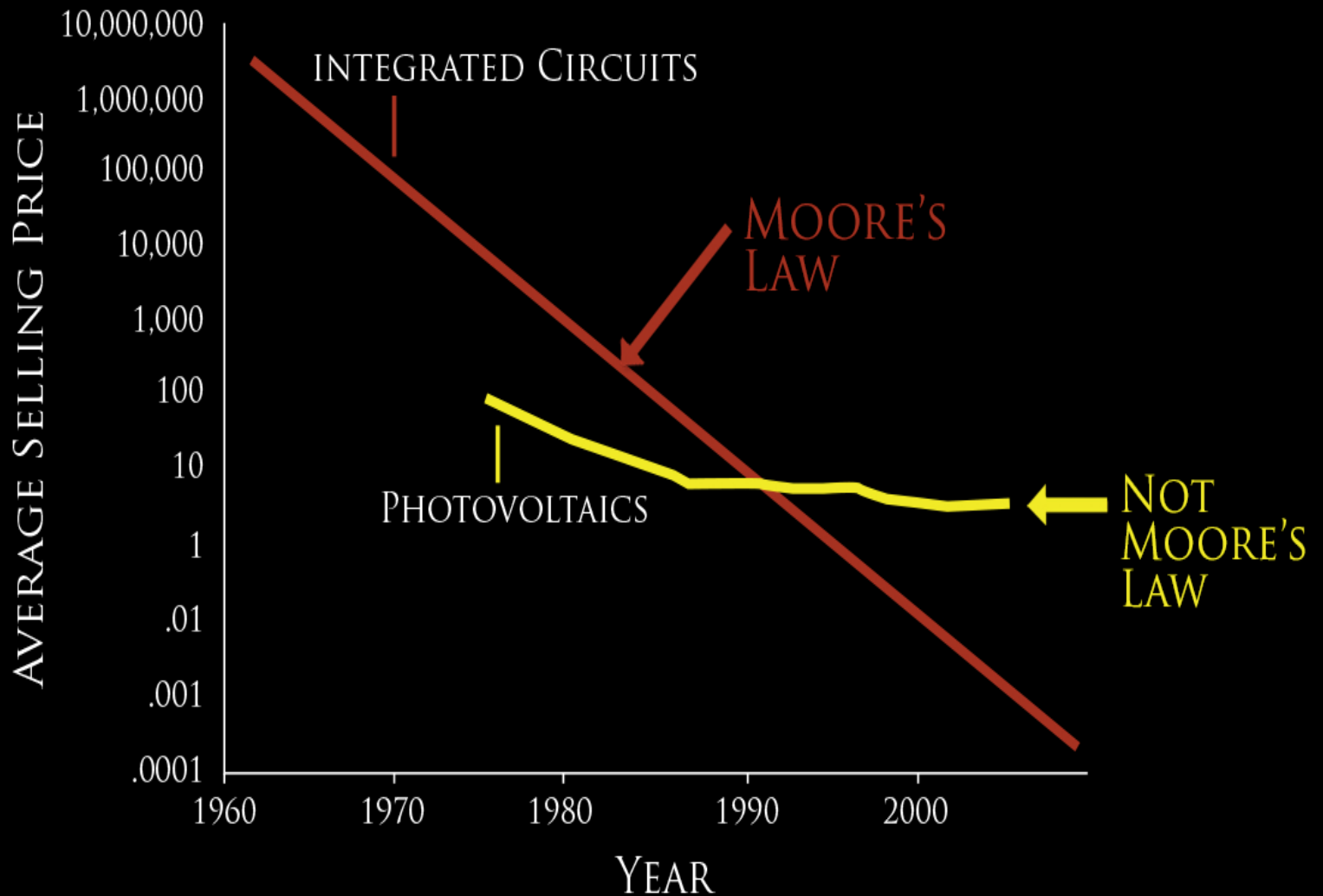
Crystalline silicon PV



Thin Film PV

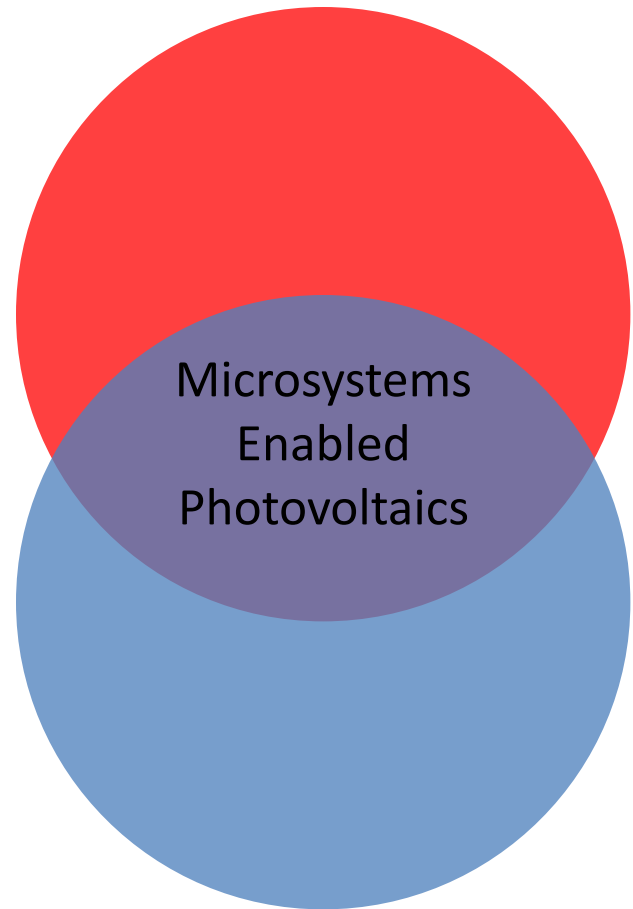
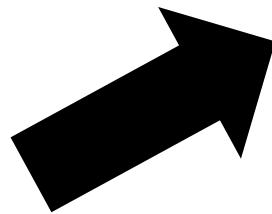
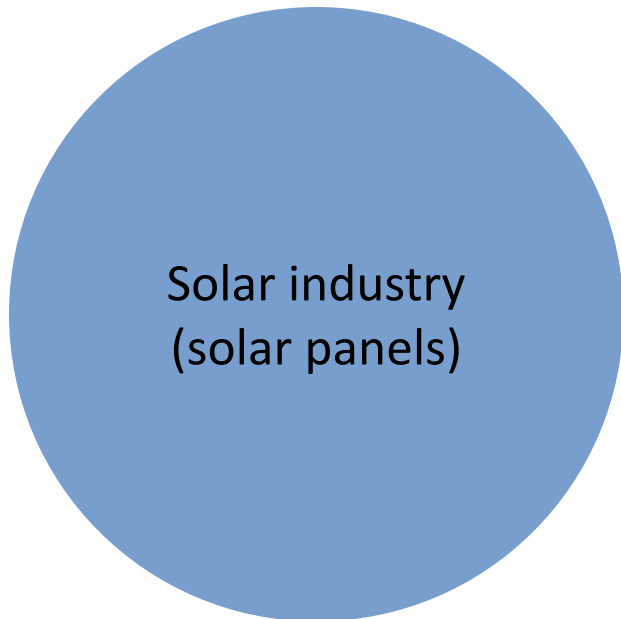
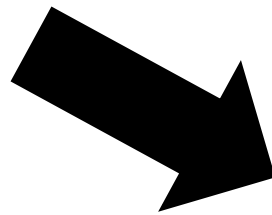
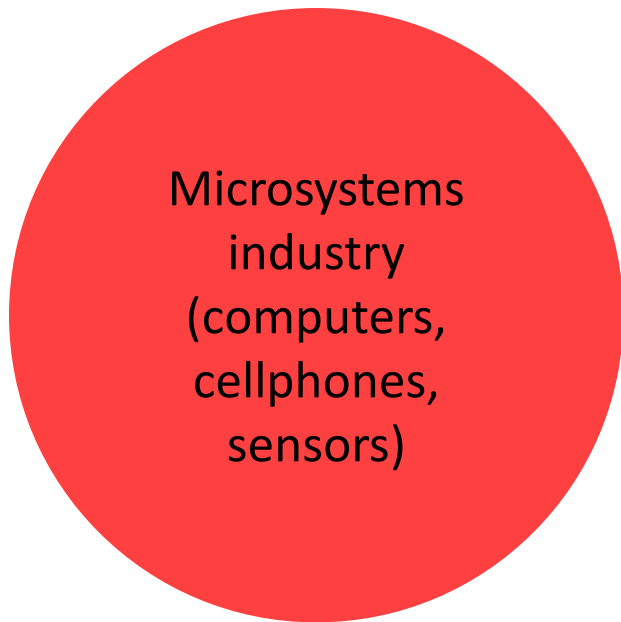


REDUCED COST

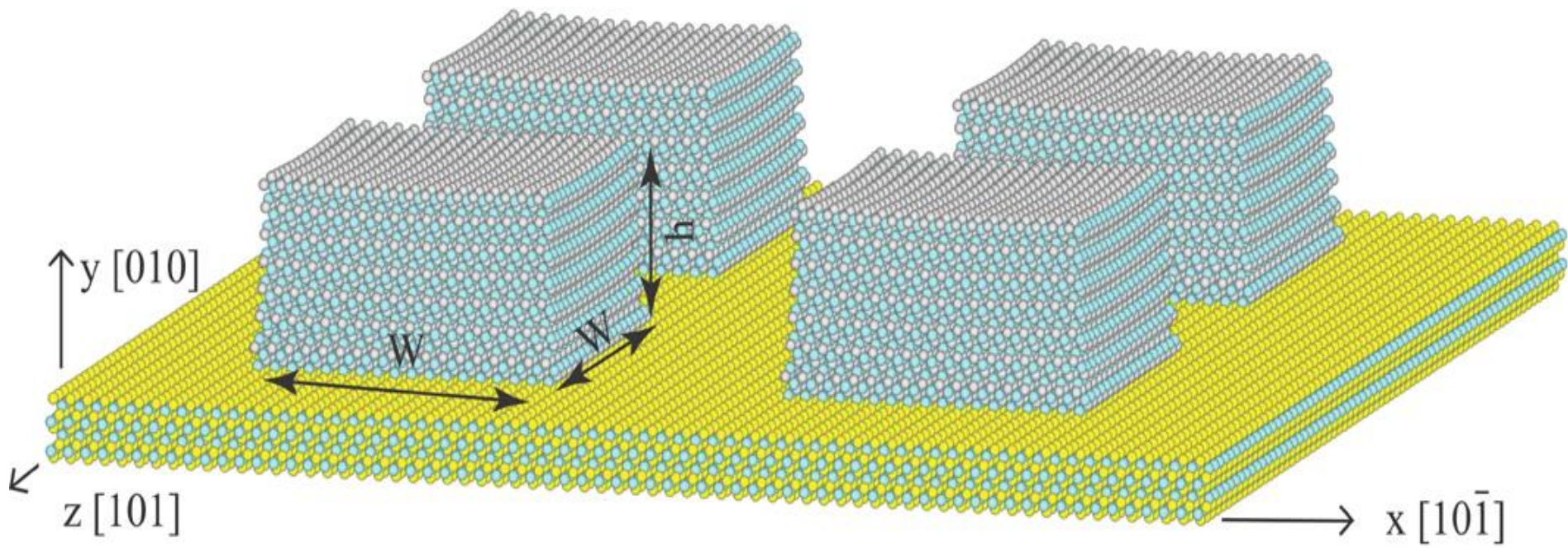


DERIVED FROM R. SINGH, JOURNAL OF NANOPHOTONICS, VOL. 3, 2009

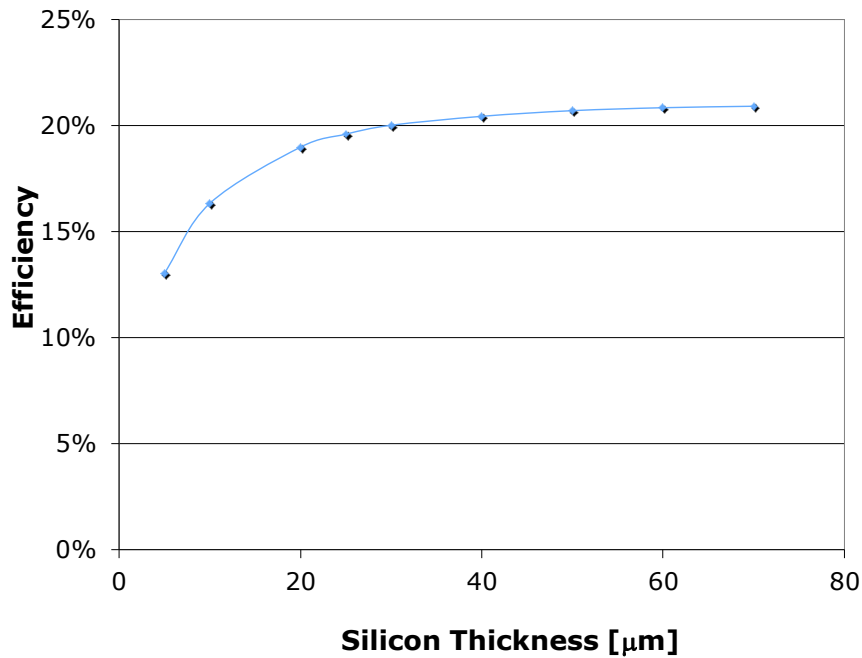
— AVERAGE SELLING PRICE OF INTEGRATED CIRCUITS (\$)
— AVERAGE SELLING PRICE OF PHOTOVOLTAICS (\$ PER WATT)



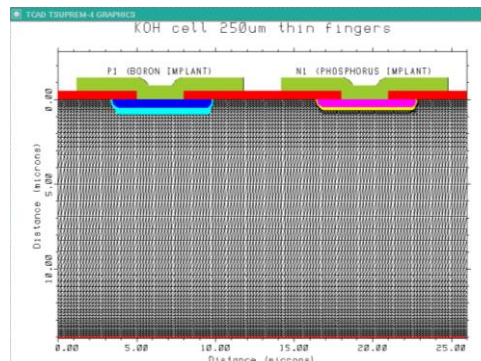
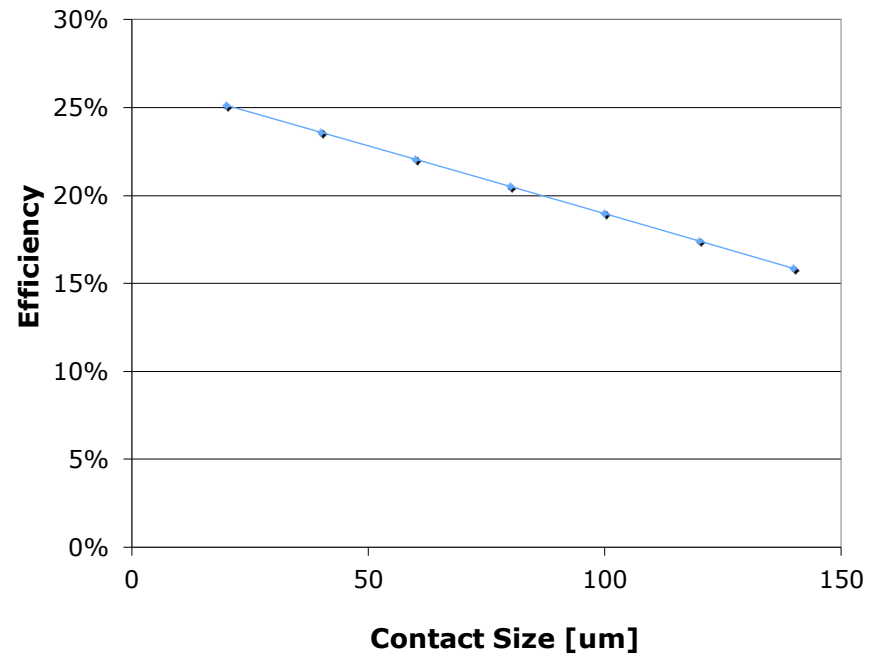
3 examples motivating the research

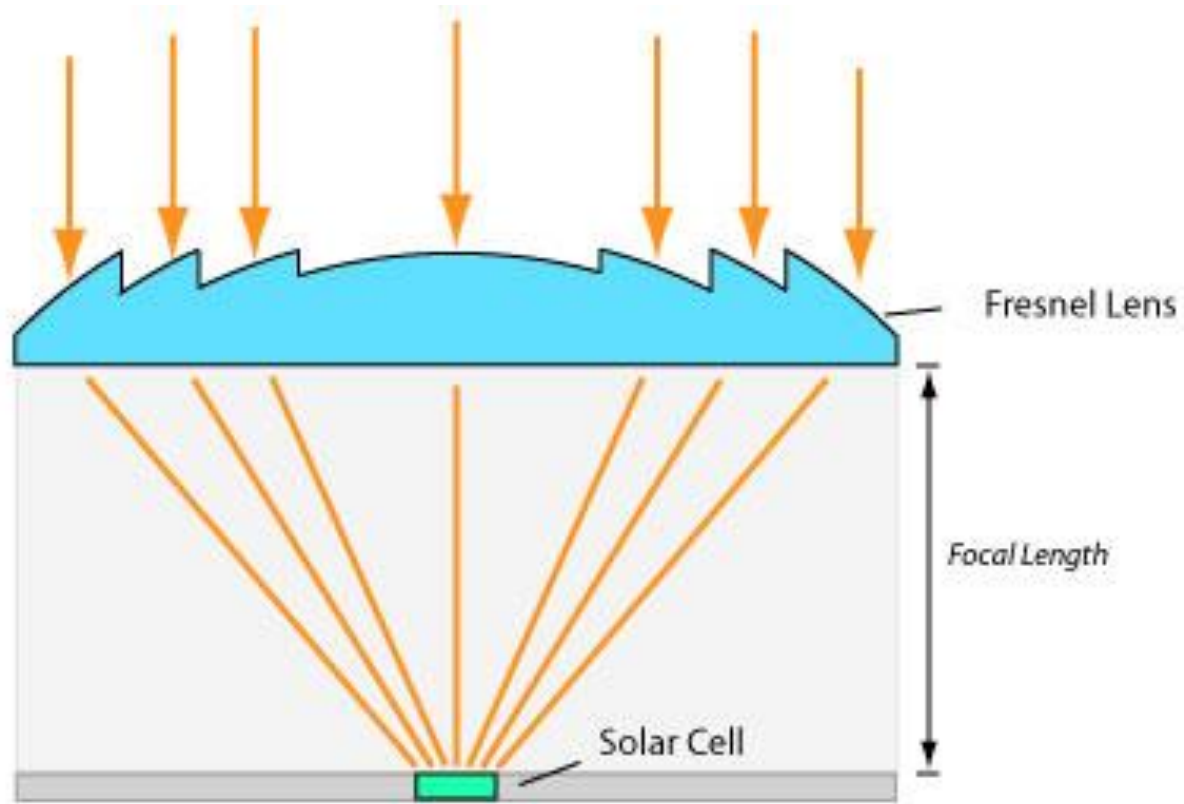


1 Sun: Efficiency vs Silicon Thickness



1 Sun: Efficiency vs Contact Size





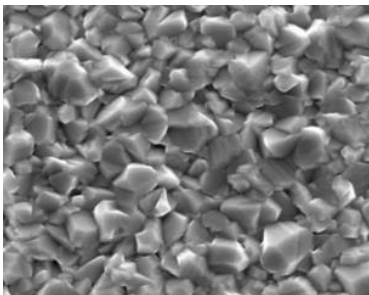
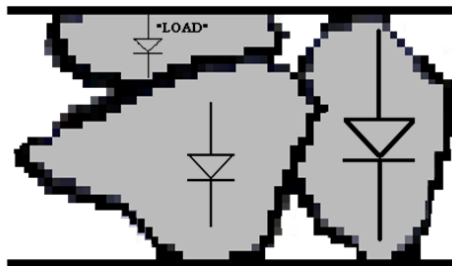
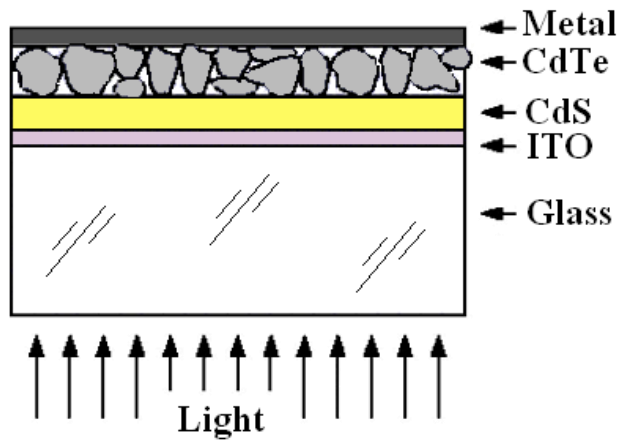
With the advantages of using microsystems and small cells, a new area of research was born

With the advantages of using microsystems and small cells, a new area of research was born

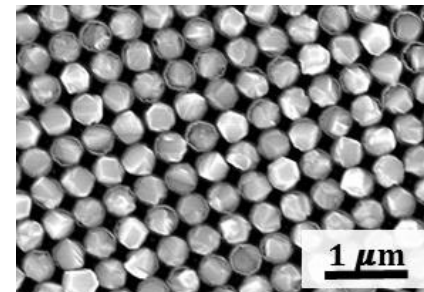
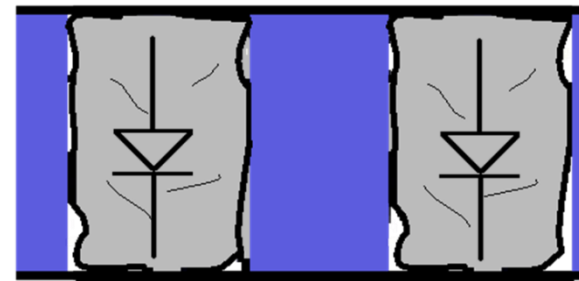
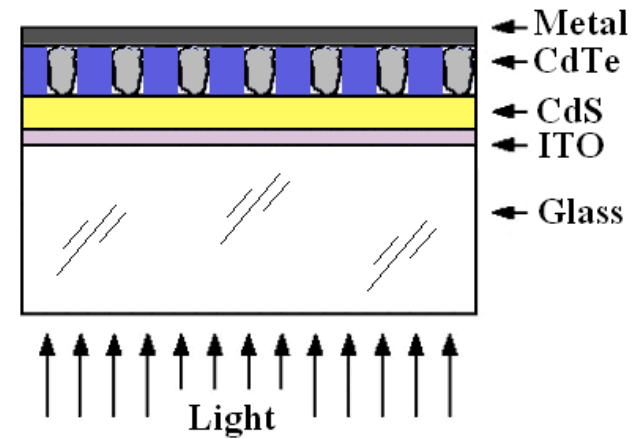
Thin Film PV



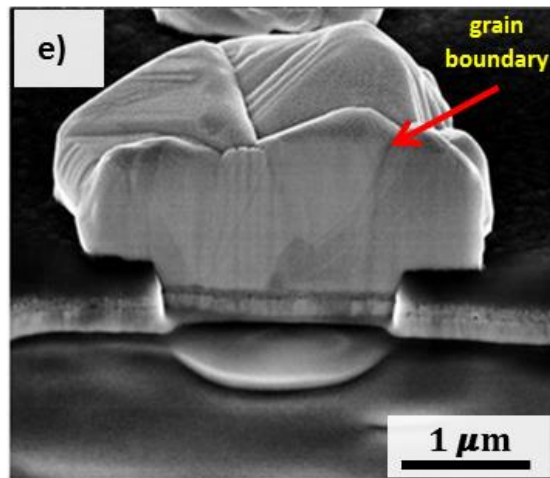
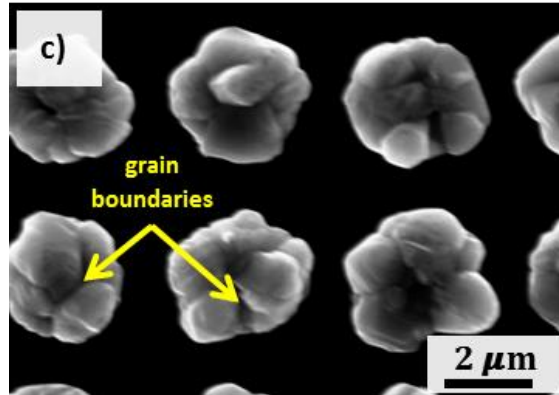
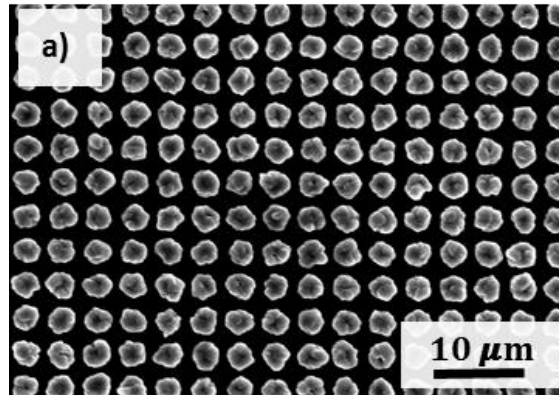
Normal cell



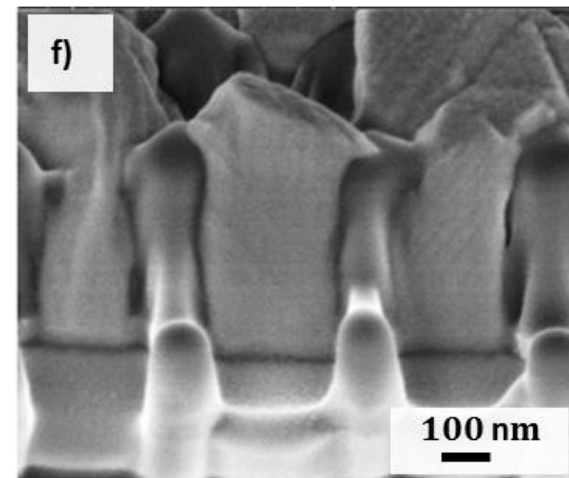
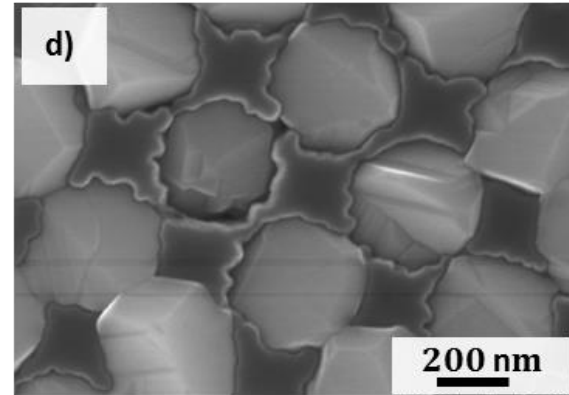
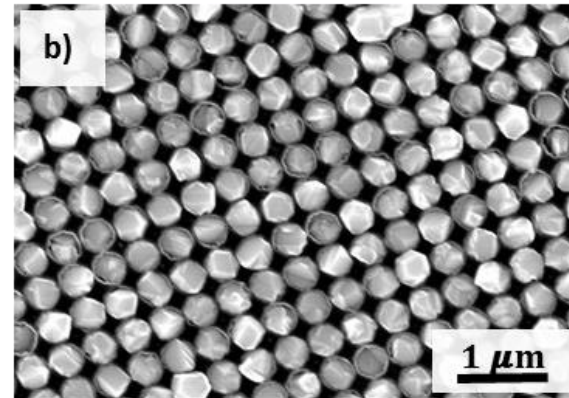
Microsystems enabled cell



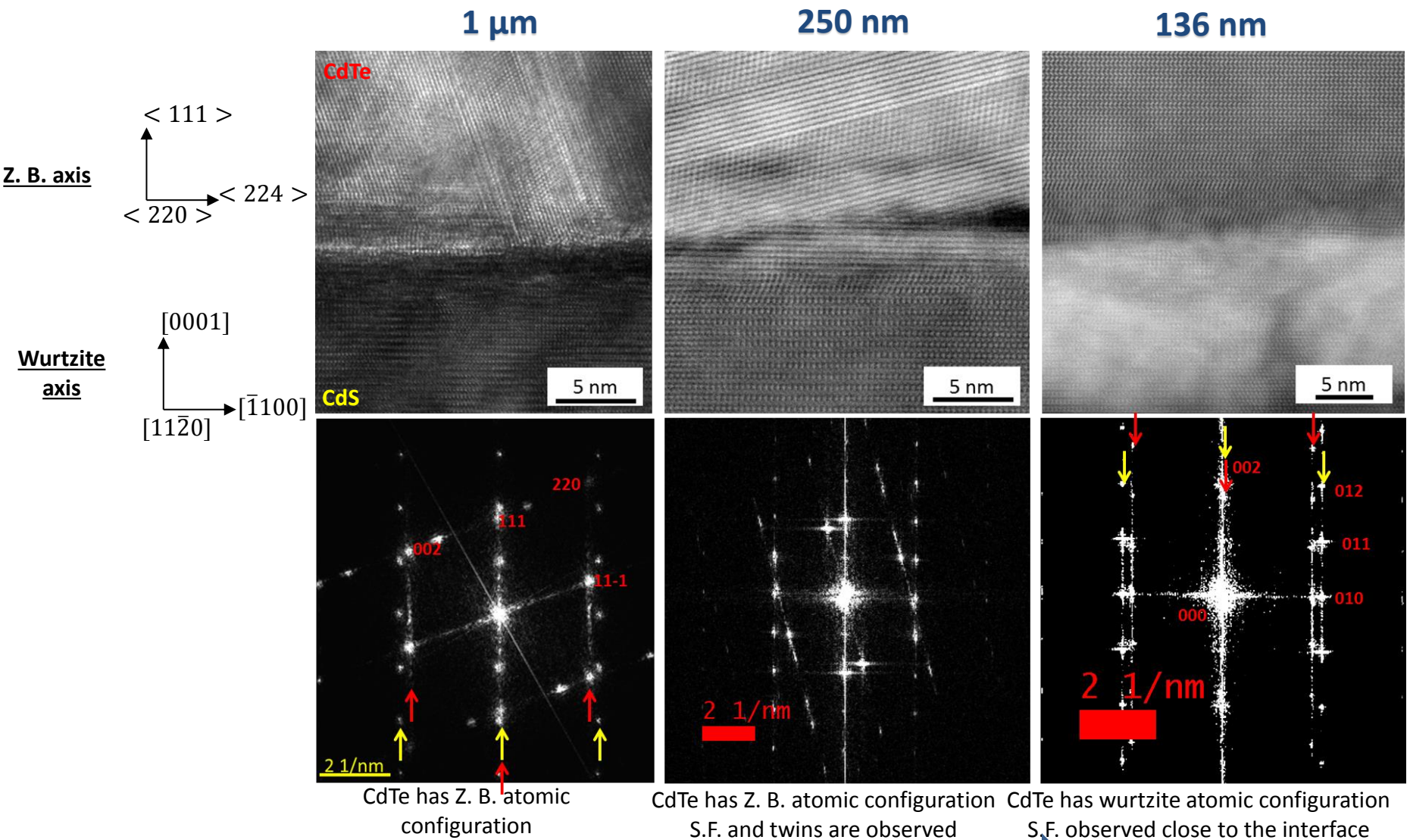
Micro-pattern



Nano-pattern



Brandon A. Aguirre, Jose L. Cruz-Campa et. al "Selective Growth of CdTe on Nano-patterned CdS via Close-Space Sublimation", Journal of Electronic Materials, 43, 2014 pp 2651-2657



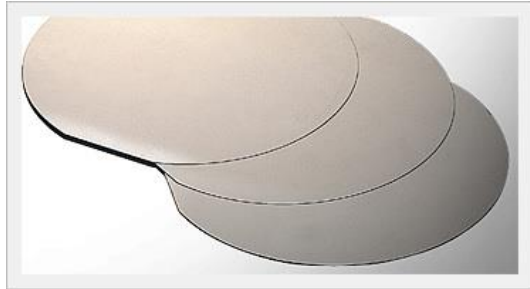
Reduction of island size

Material quality improves

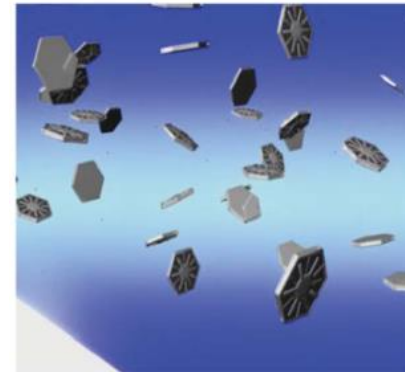
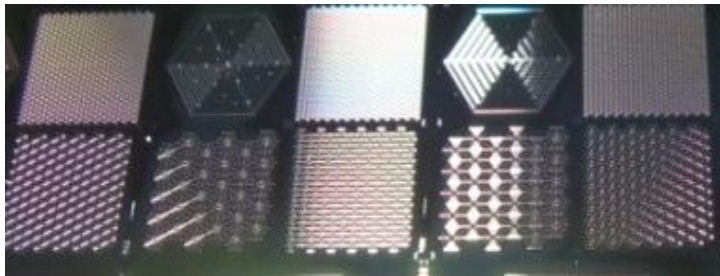
Crystalline silicon PV

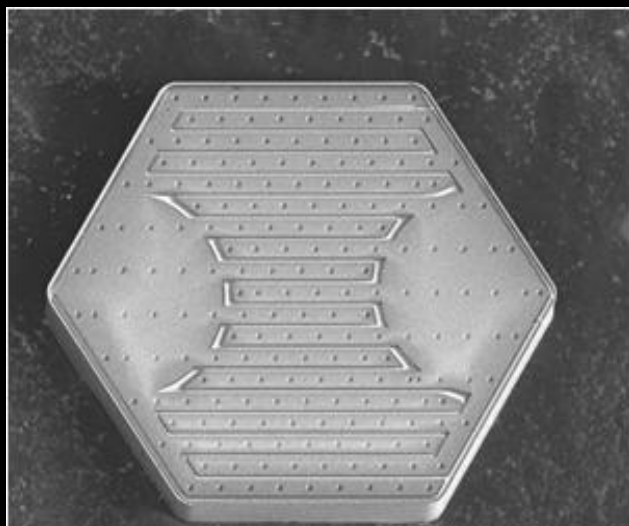


Conventional process

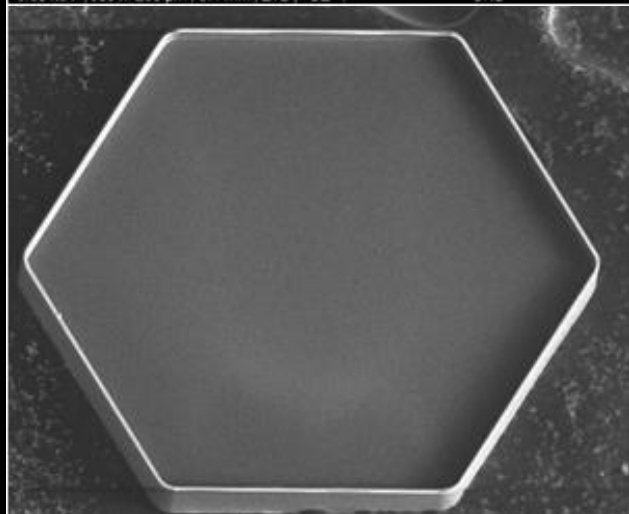


Sandia Process

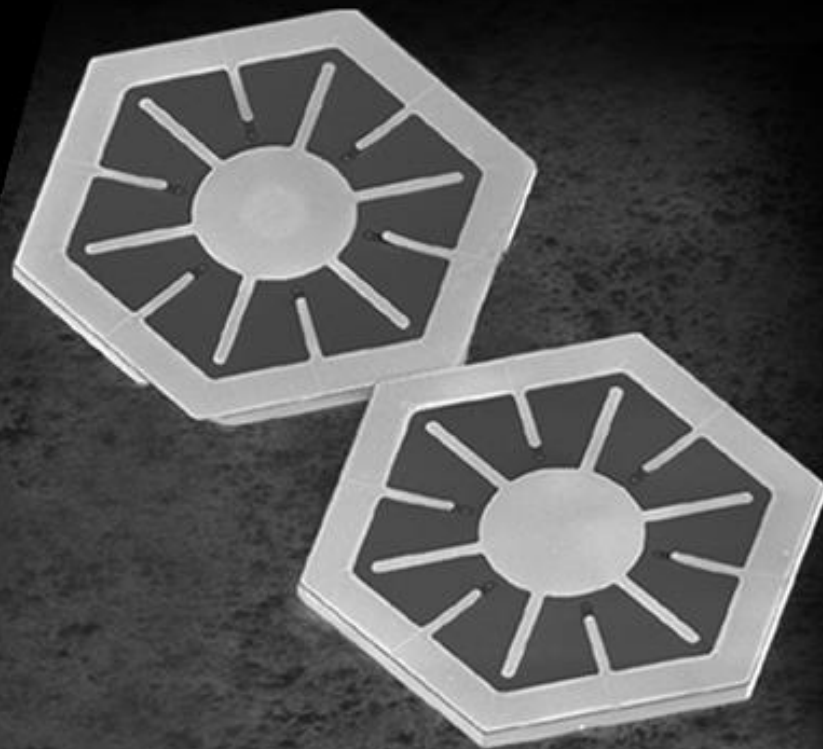




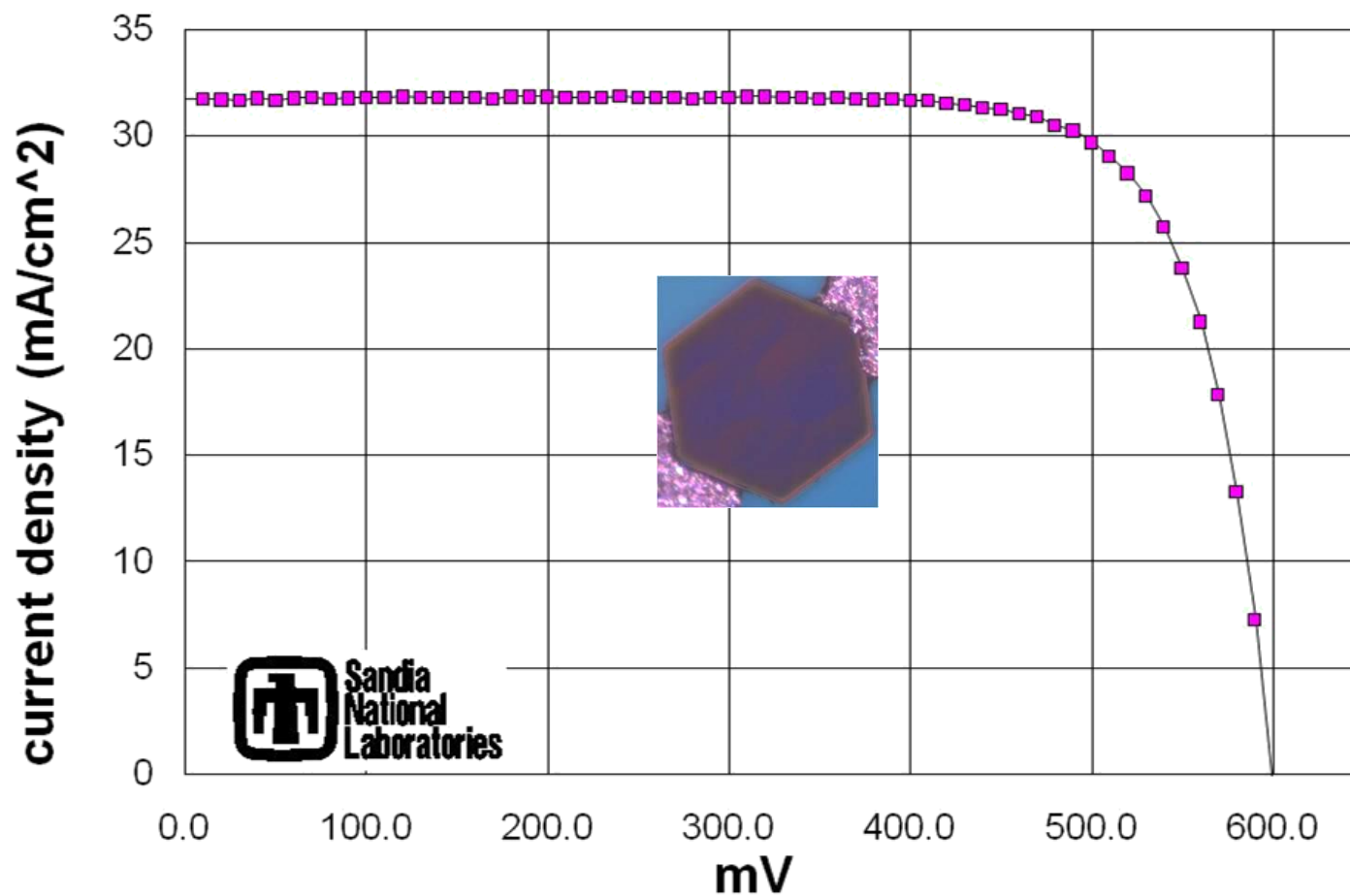
Landing E	mag	HPW	WD	det	mode	100 μ m
5.00 keV	500 x	298 μ m	5.1 mm	ETD	SE	SNL



Landing E	mag	HPW	WD	det	mode	100 μ m
5.00 keV	567 x	263 μ m	5.1 mm	ETD	SE	SNL



500
MICROMETERS



08/20/09 2:18 PM

25.0 °C

0.0003763 cm²

31.75 J_{sc}(mA/cm²)

0.784 FF

AM1.5G

1.0000 M*

597.3 V_{oc}(mV)

11.946 I_{sc}(uA)

14.86 % Eff

1.00 Suns

1.0000 S*

501. V_{mp}(mV)

11.161 I_{mp}(uA)

1

Interconnect substrate

2

Interconnect substrate

CELLS

Donor wafer

CELLS

Donor wafer

3

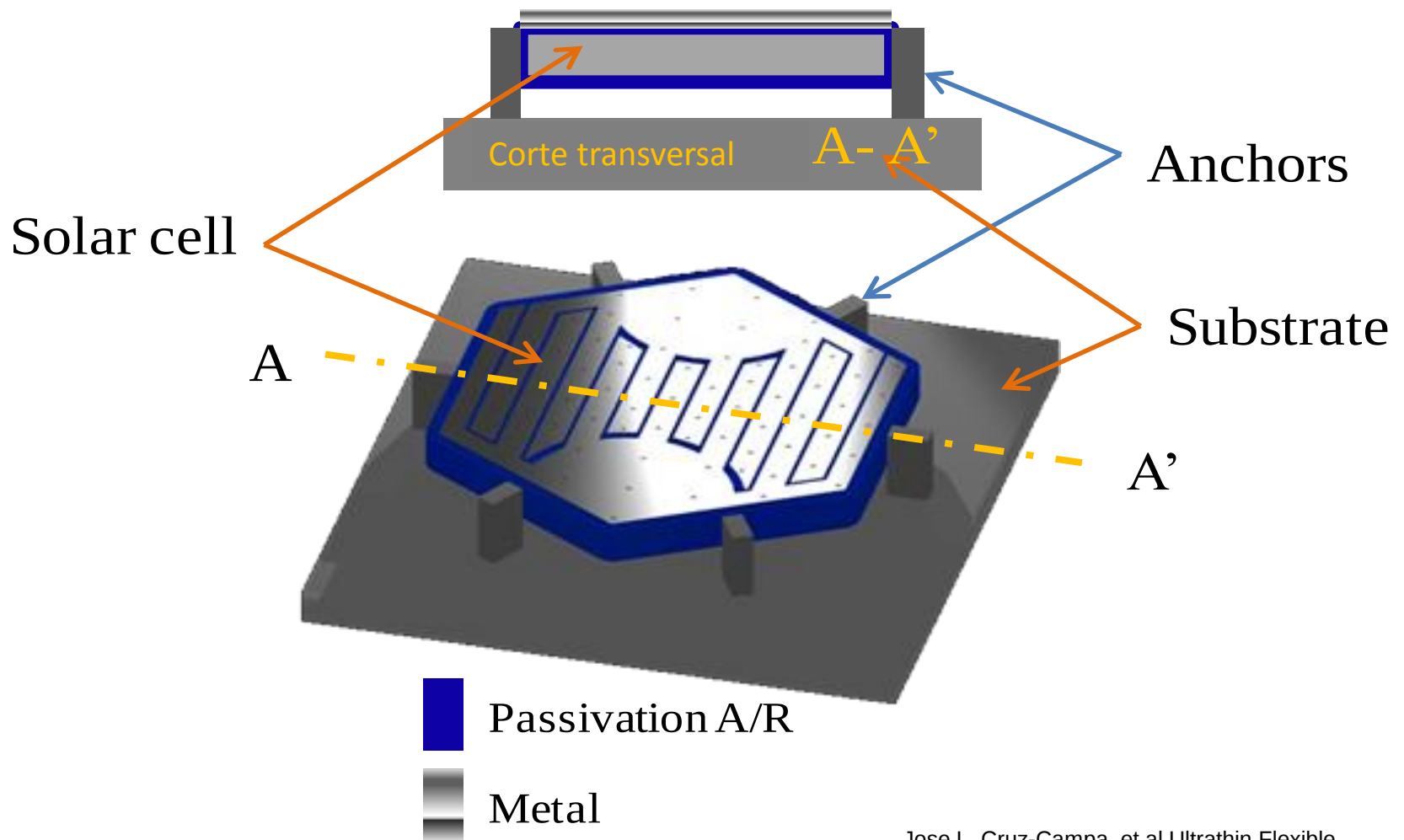
Interconnect substrate

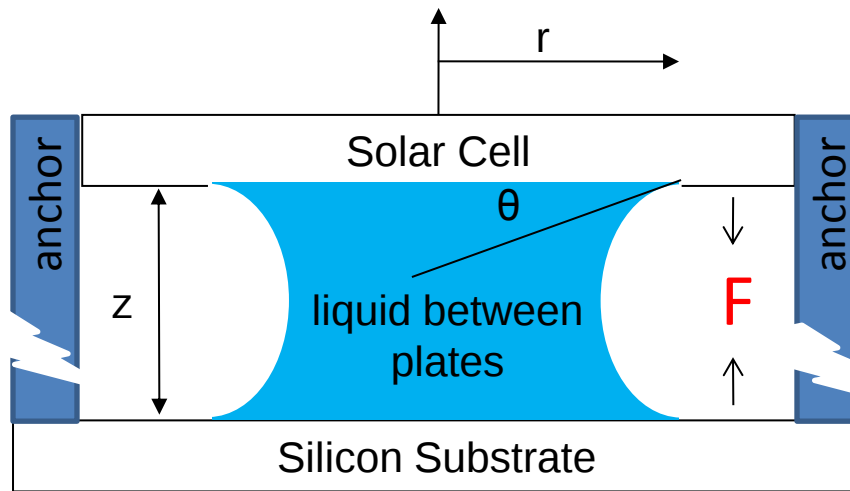
CELLS

Donor wafer

Advantages:

- Less handling
- Less placements per module
- Higher uniformity





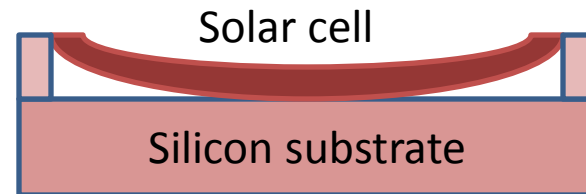
capillary forces

$$\sigma = \frac{F}{wt * \#anchors}$$

$$F = \frac{2\pi\gamma}{z} r^2 \cos\theta$$

Deflection

$$\delta = \frac{Fr^3}{(48)EI}$$



Spinning

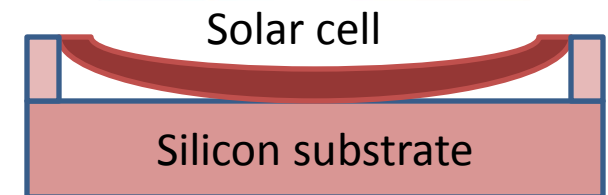
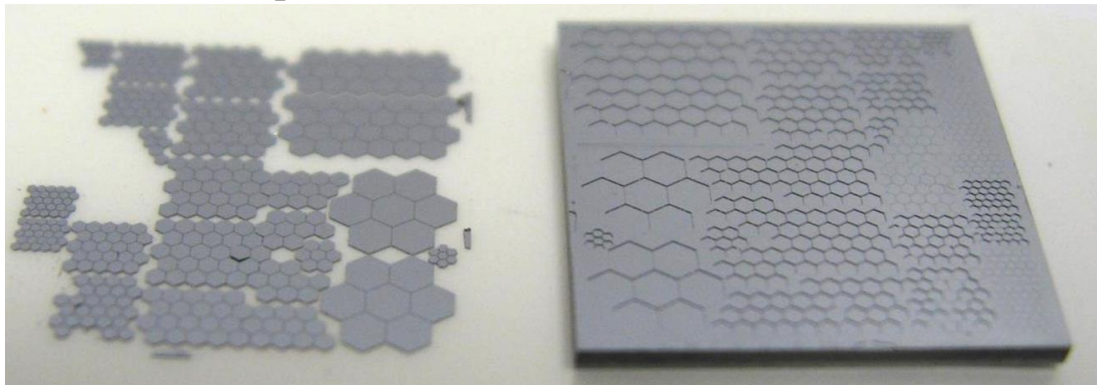
Lateral size (μm)	3 anchors	6 anchors middle	6 anchors corners	6 spring anchors	12 anchors	18 anchors
250	☺	☹	☹	☺	☹	☹
375	☺	☺	☹	☺	☹	☹
500	☺	☺	☺		☺	☺
750		☺			☺	☺
1000					☹	☺

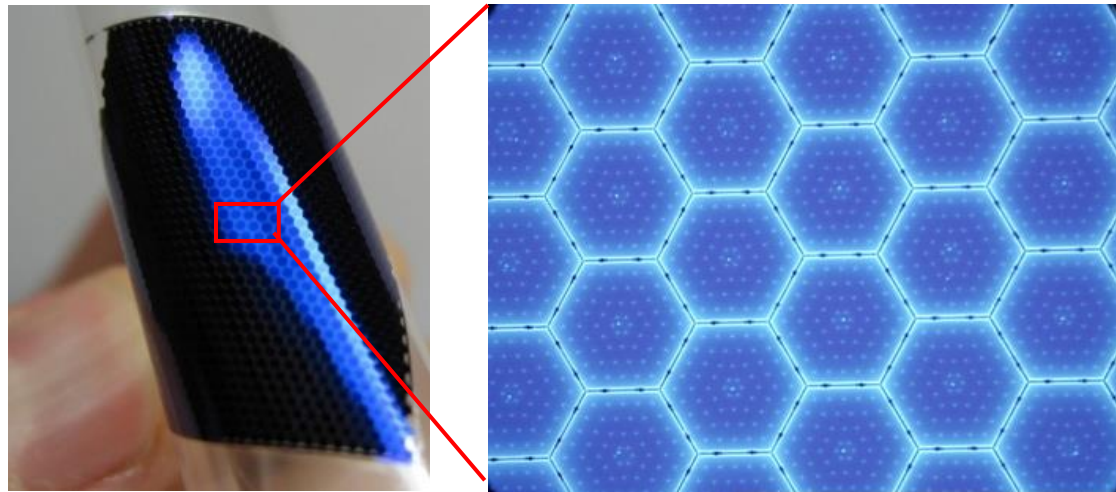
☐ design fabricated ☐ design not fabricated

☺ Successful (suspended/transferred)

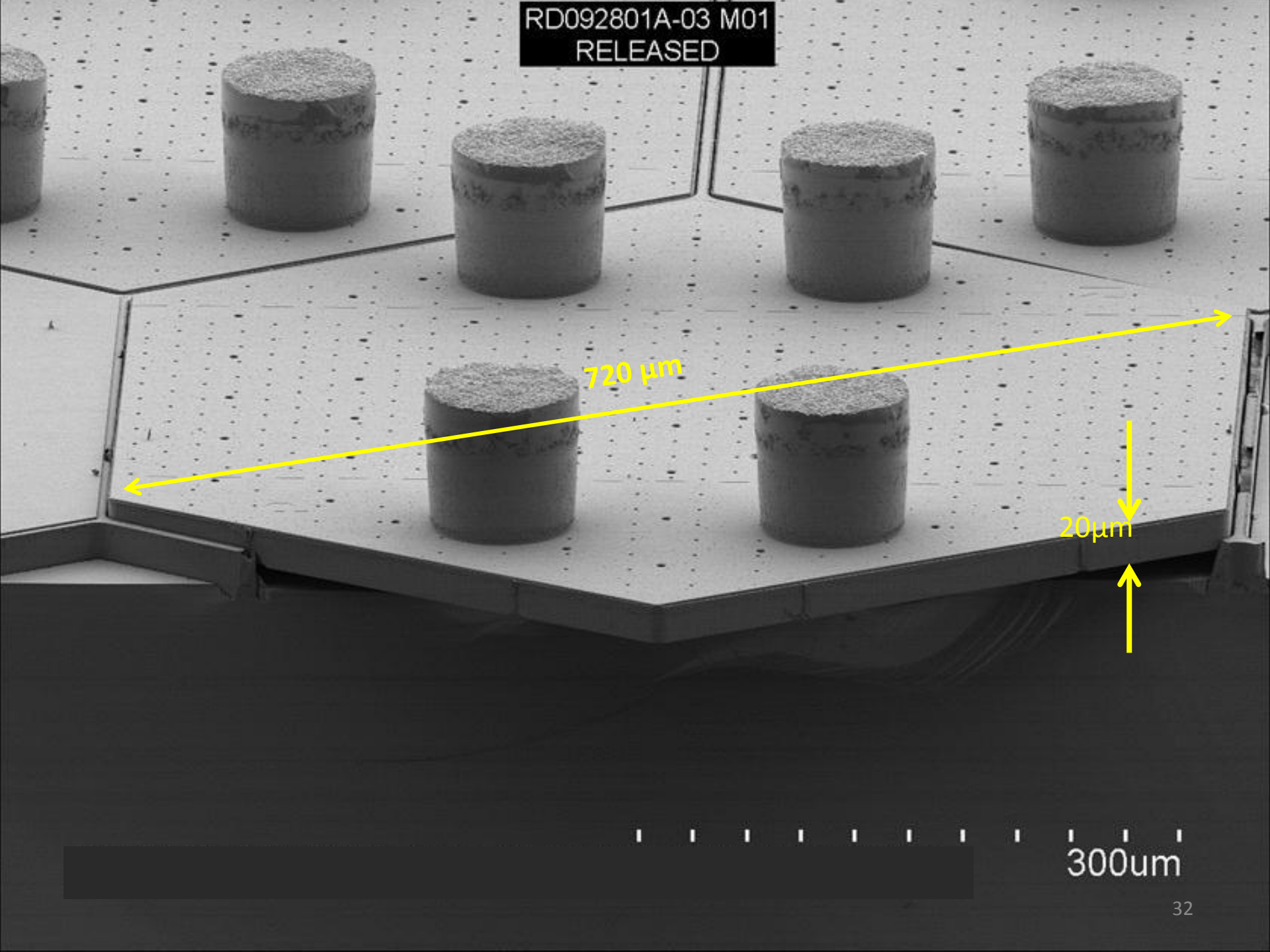
☹ suspended/ not transferred

⊗ Not suspended





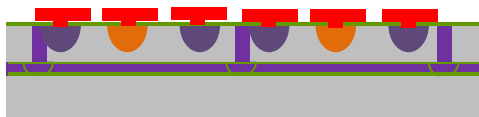
RD092801A-03 M01
RELEASED



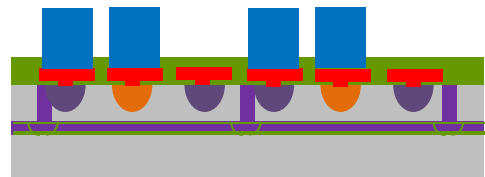
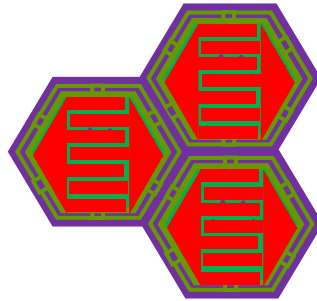
720 μm

20 μm

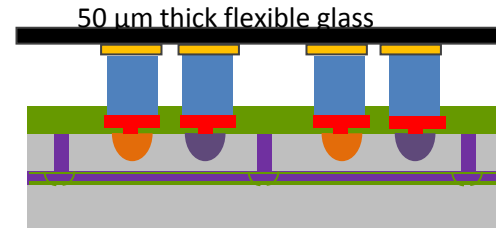
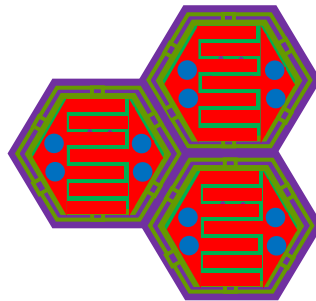
300 μm



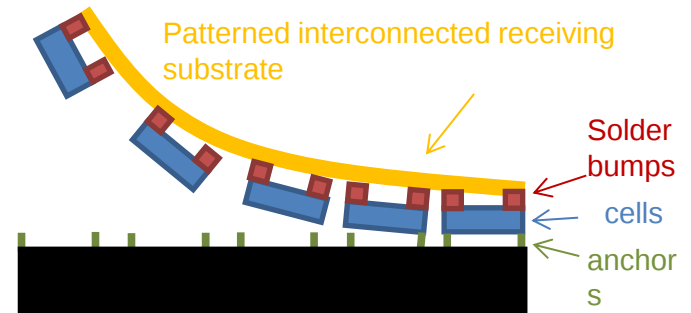
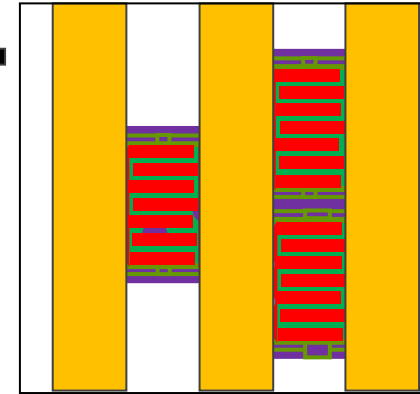
Finished cell with metallization



Nitride deposition and pattern and solder bump creation

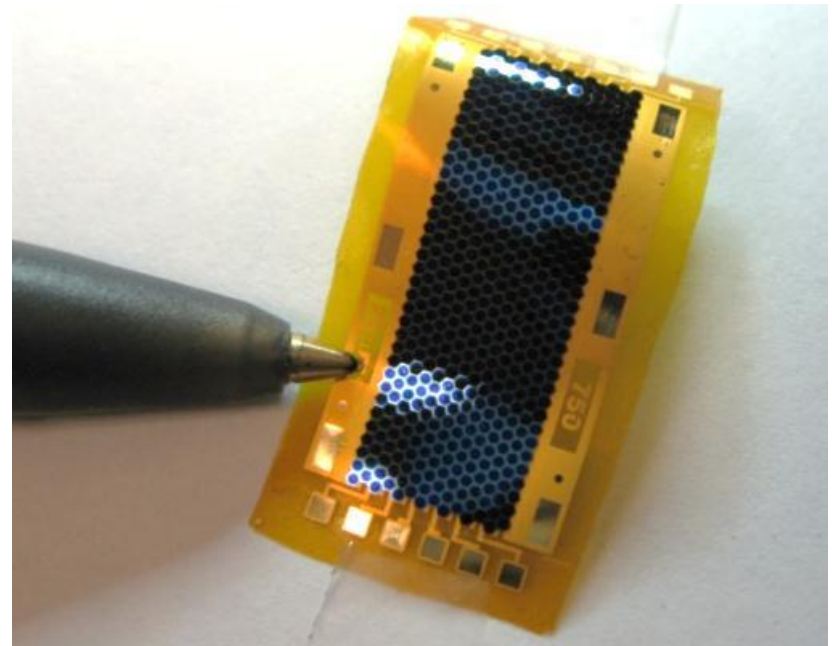
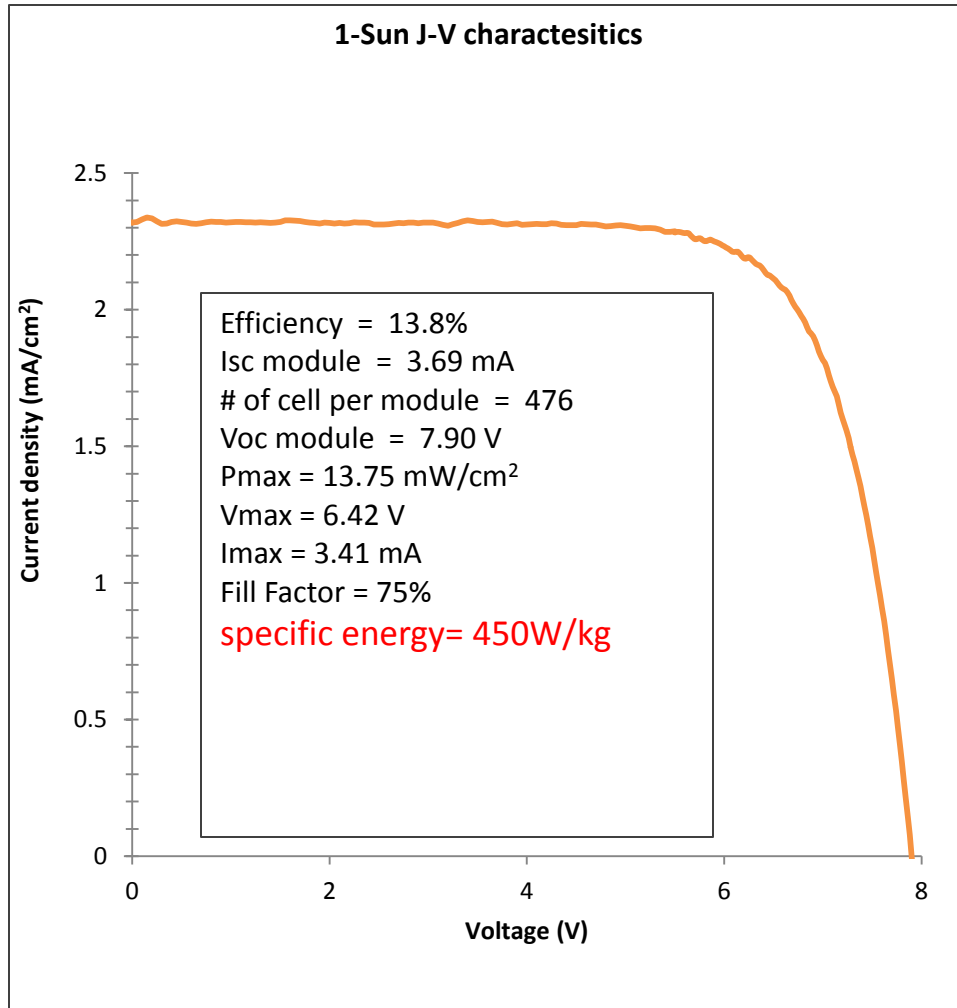


XeF2 etch and bump metal melt to mechanically and electrically connect to receiving substrate



Detachment of cells

Sandia is the first one to prove such a high energy density with such a small bending radius





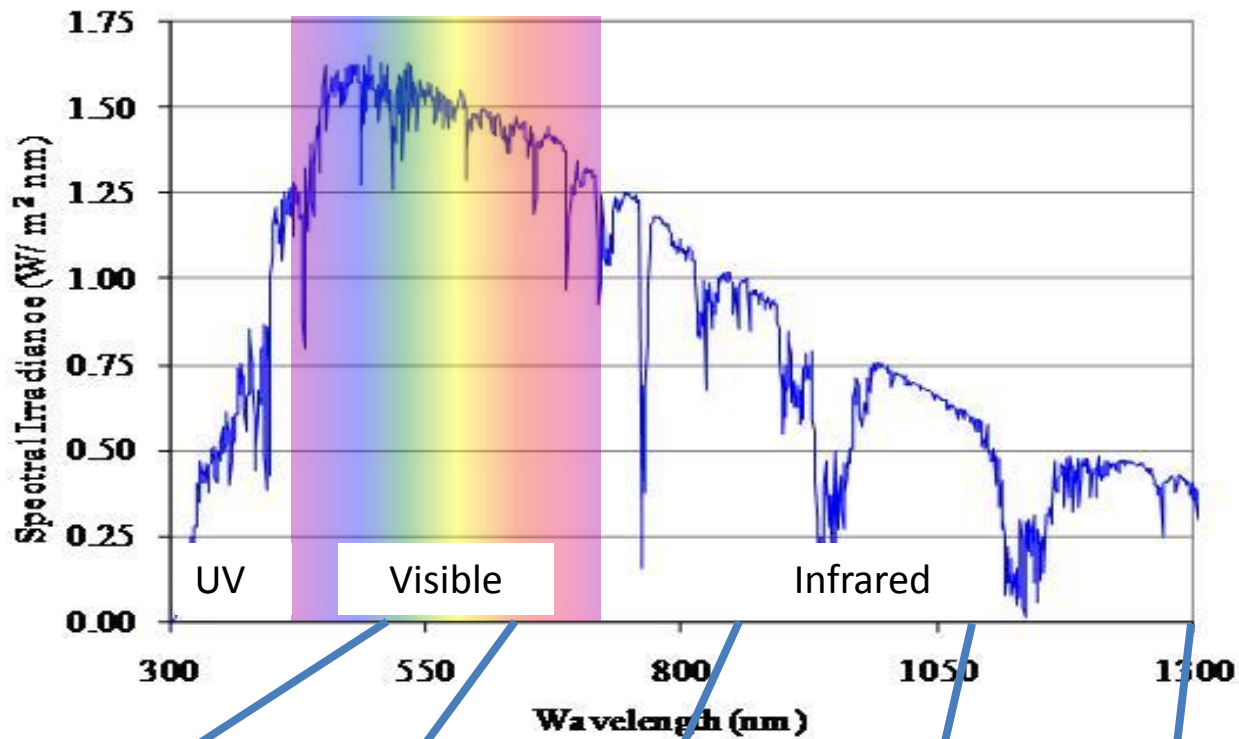
IMPROVED PERFORMANCE

NEW FUNCTIONALITY

Concentrated PV

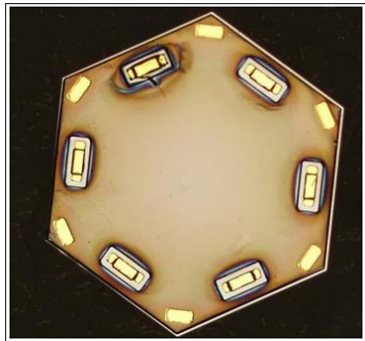


ASTMG173-03 Reference Spectra

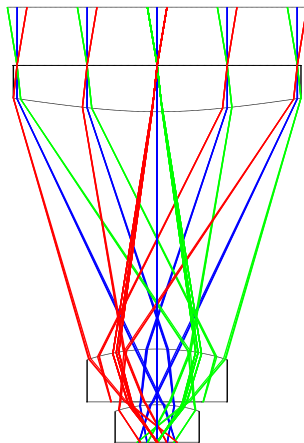


Material	InGaN 2.2 eV	InGaP 1.85eV	GaAs 1.4eV	Si 1.1eV	InGaAsP 0.9eV	InGaAs 0.6eV
Wavelengths best absorbed	Less than 560nm	Less than 670nm	Less than 886nm	Less than 1127nm	Less than 1378nm	Less than 2070nm

Our approach has a defined path to make solar the least expensive energy source



Small cells



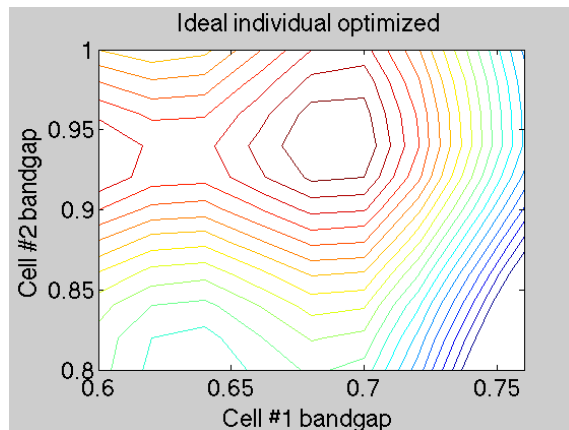
New optical refractive designs for tracking



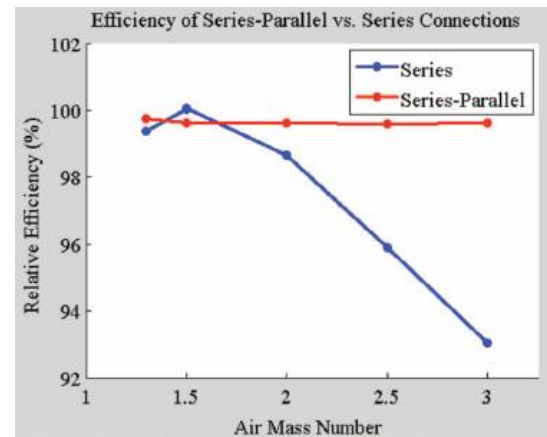
Low-cost, coarse 2-axis tracking with high acceptance angle and flat external surface



Use of mature microsystems technologies

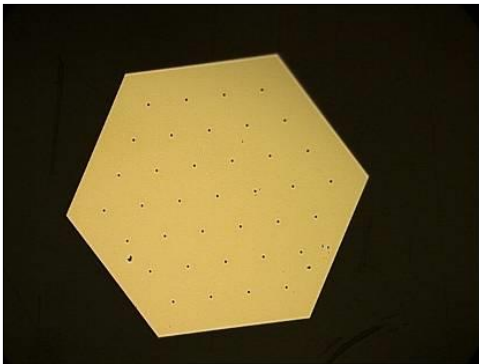
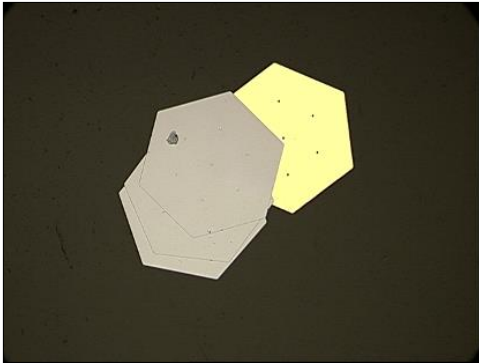


Feasibility to break the efficiency records

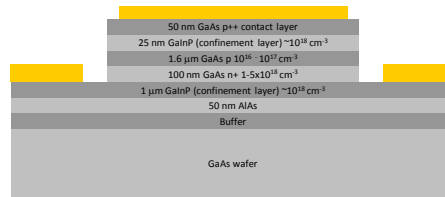


Optimized interconnections for higher efficiency

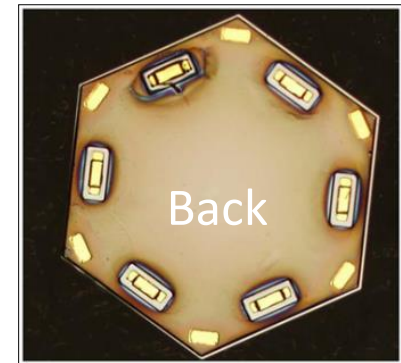
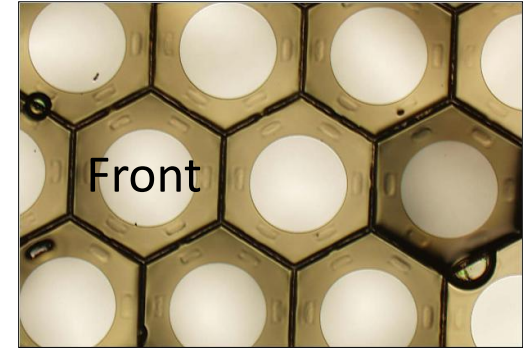
Our designs have evolved into a more complex, more functional cells



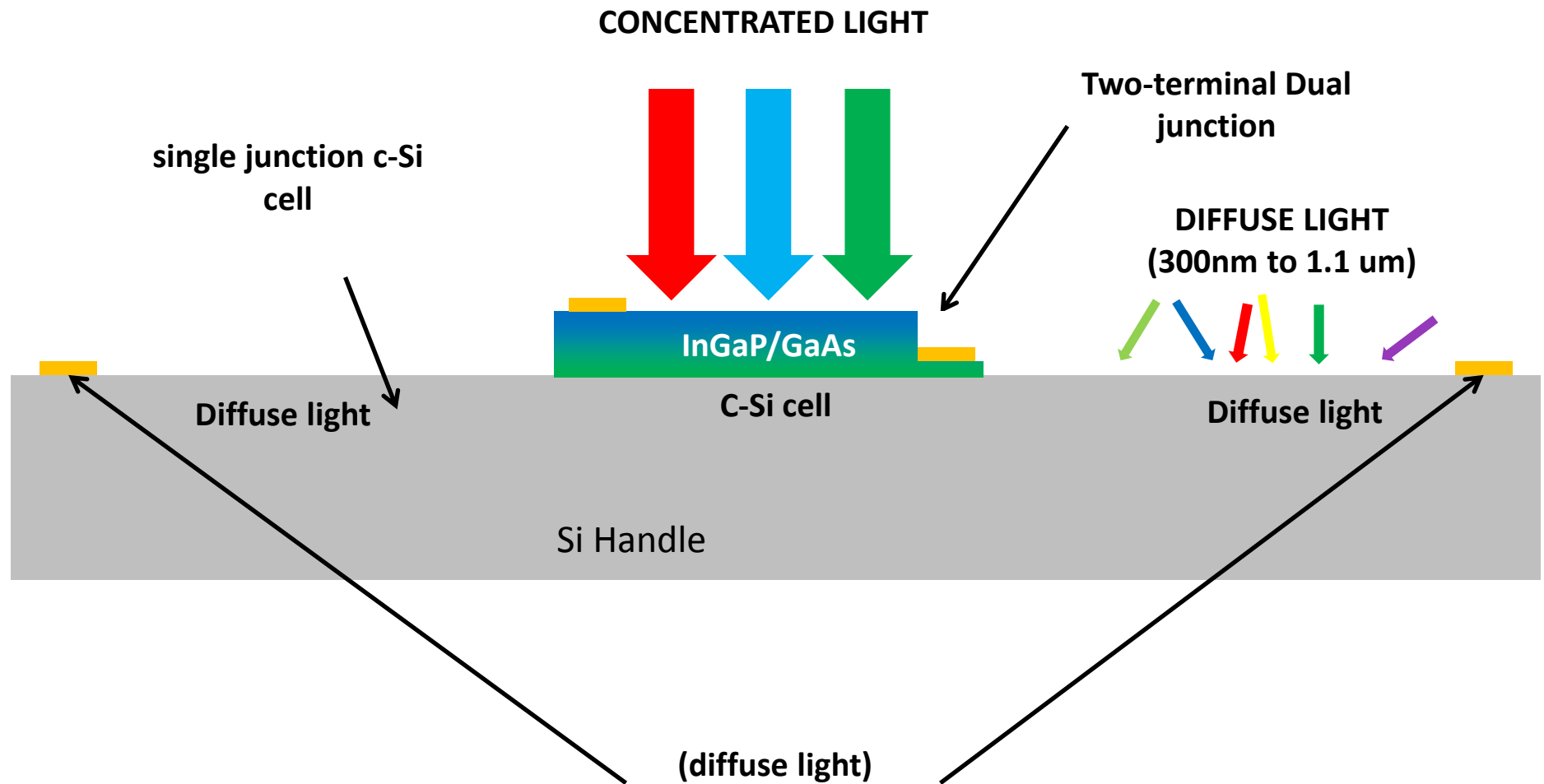
Single junction
with front-back
contacts

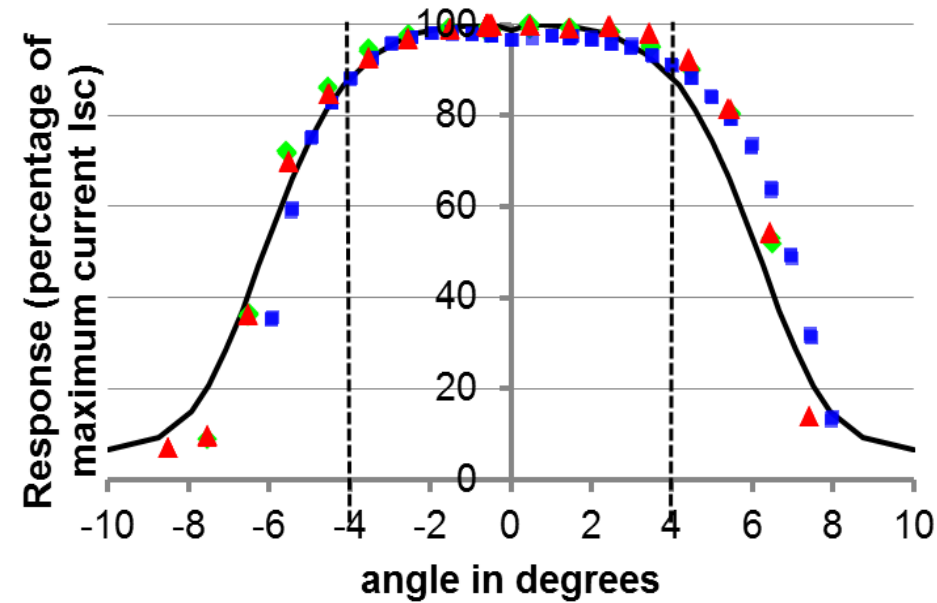
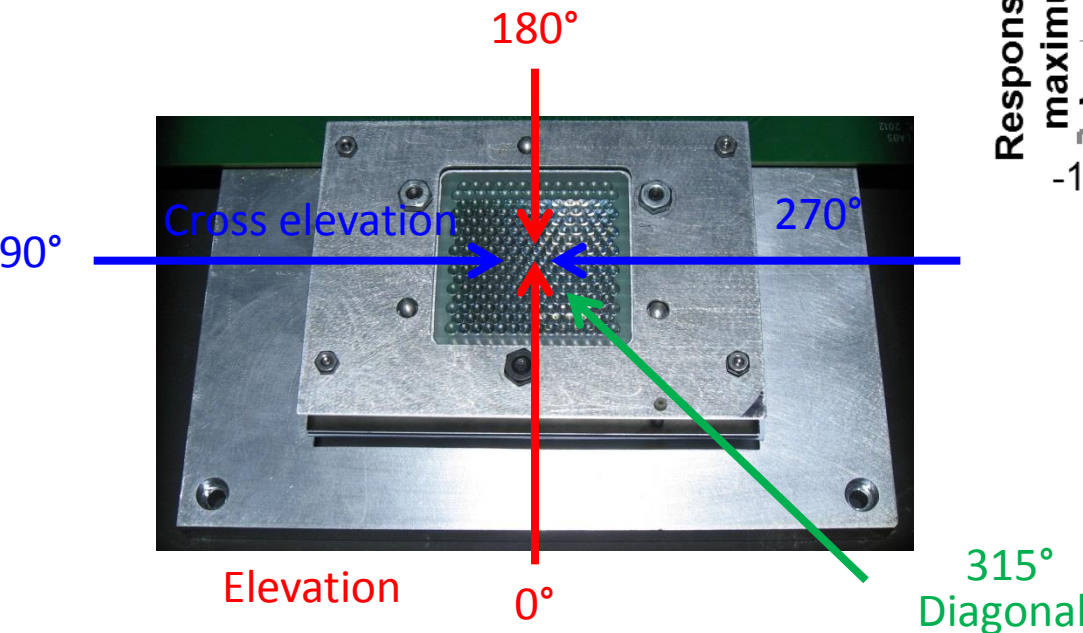


Single junction
with all back
contacts at
different levels



Double junction with all
back contacts at the
same level

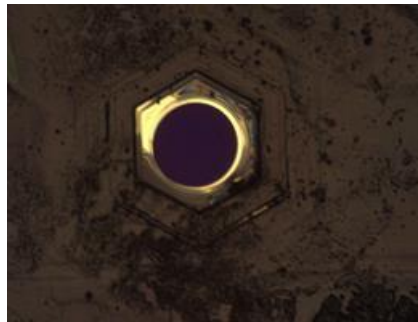
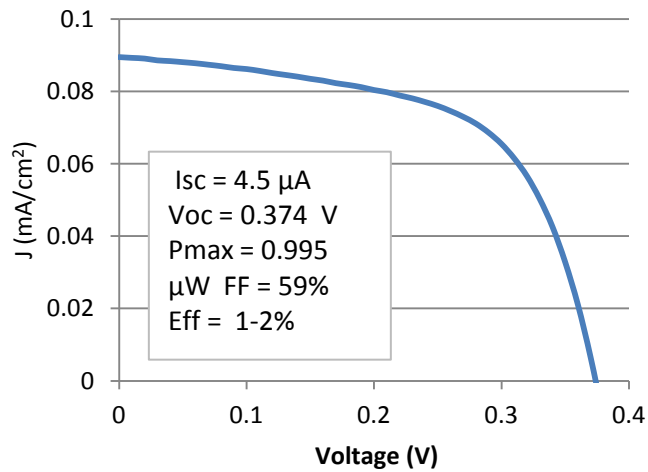




◆ Cross elevation ■ Elevation
 ▲ Diagonal — indoor testing

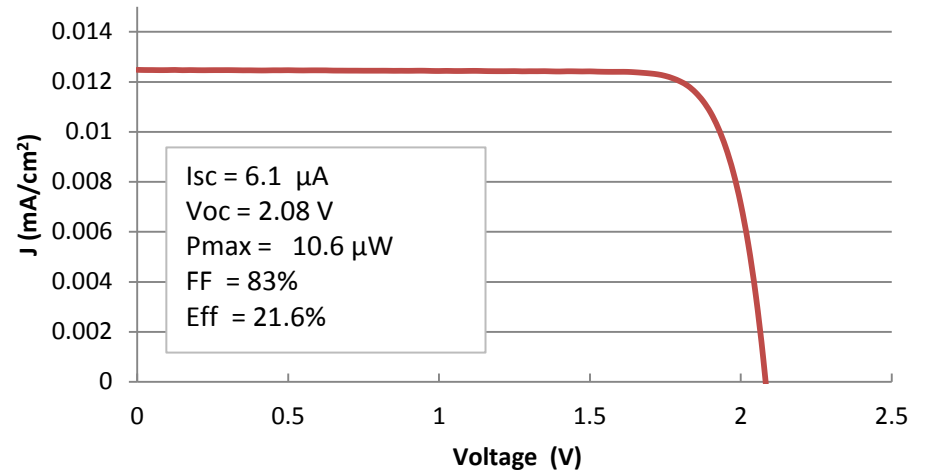
J. L. Cruz-Campa, et. al. "Flat Plate Concentrators with Large Acceptance Angle Enabled by Microcells and Mini Lenses: Performance Evaluation", 28th European Photovoltaic Solar Energy Conference and Exhibition, Pp 612 – 616, 2013

Silicon handle cell (masked)



Masked cell

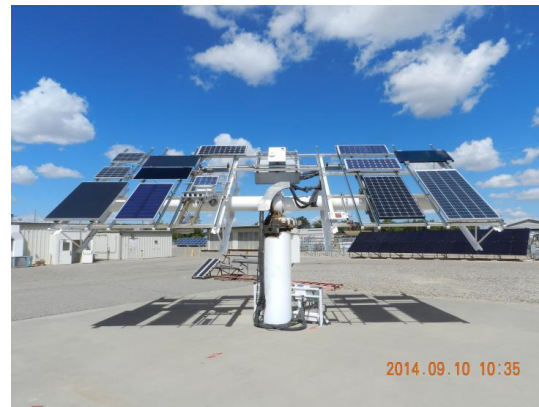
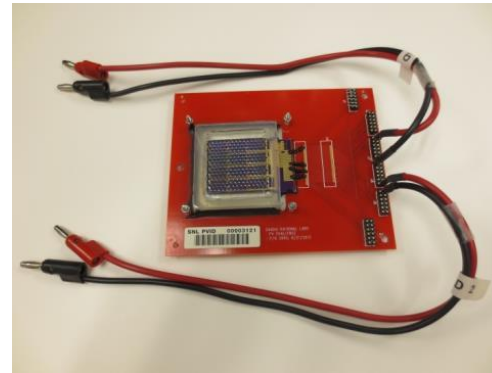
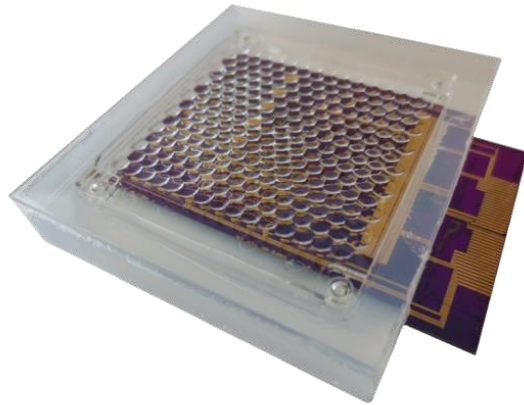
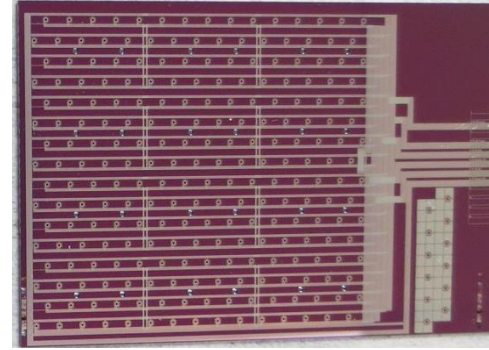
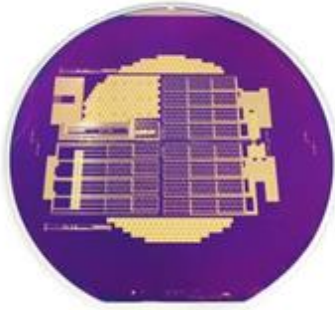
JV curve for III-V solar cell



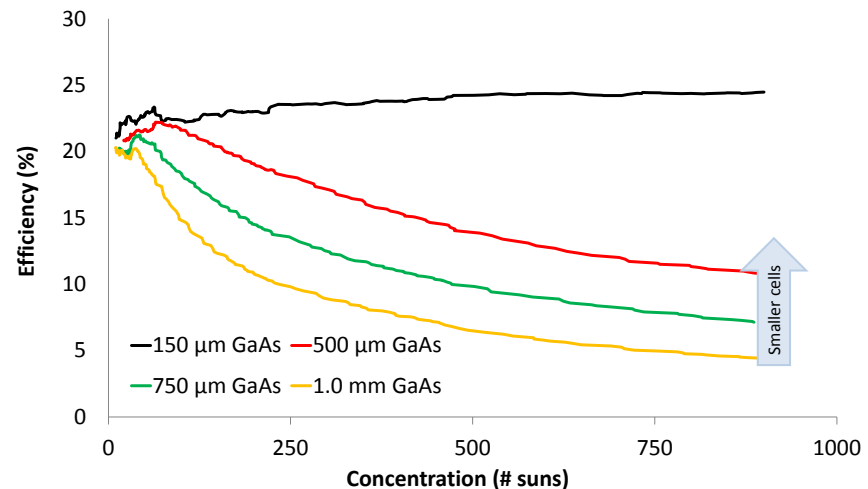
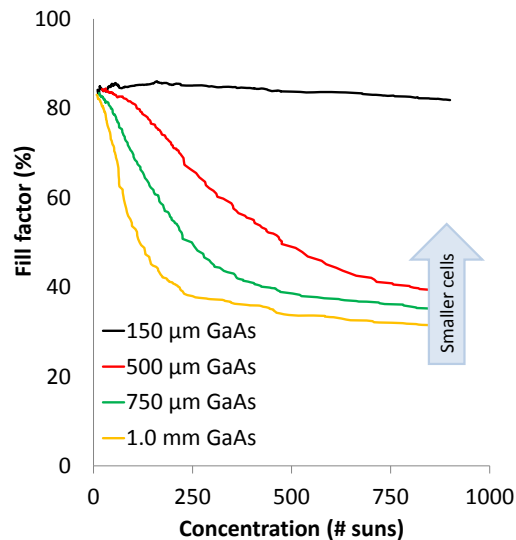
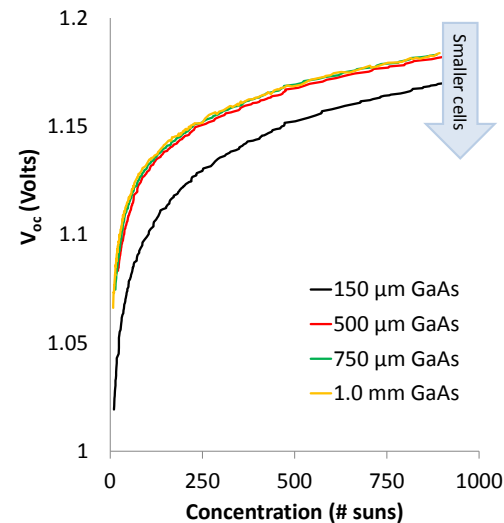
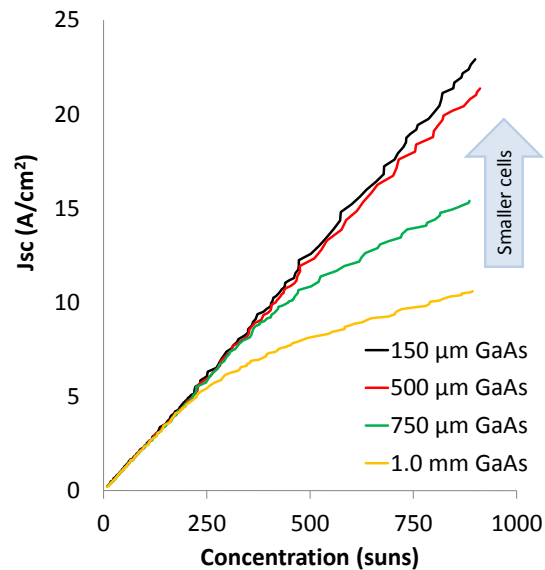
Unmasked cell

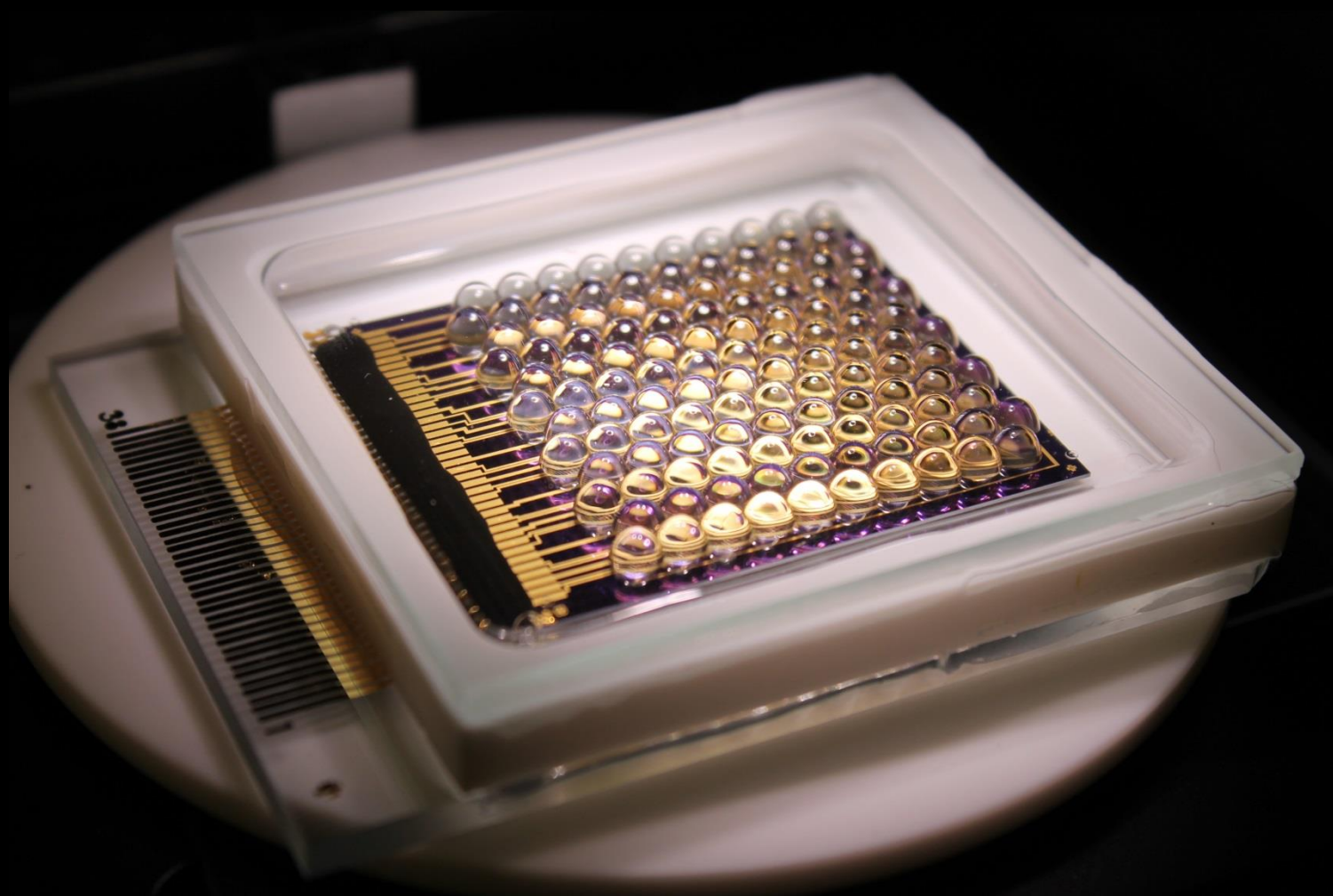
efficiencies > 21% (III-V side) with an active silicon efficiency of about 1-2%

Packaging of active cells into modules was achieved yielding optical efficiencies above 90%



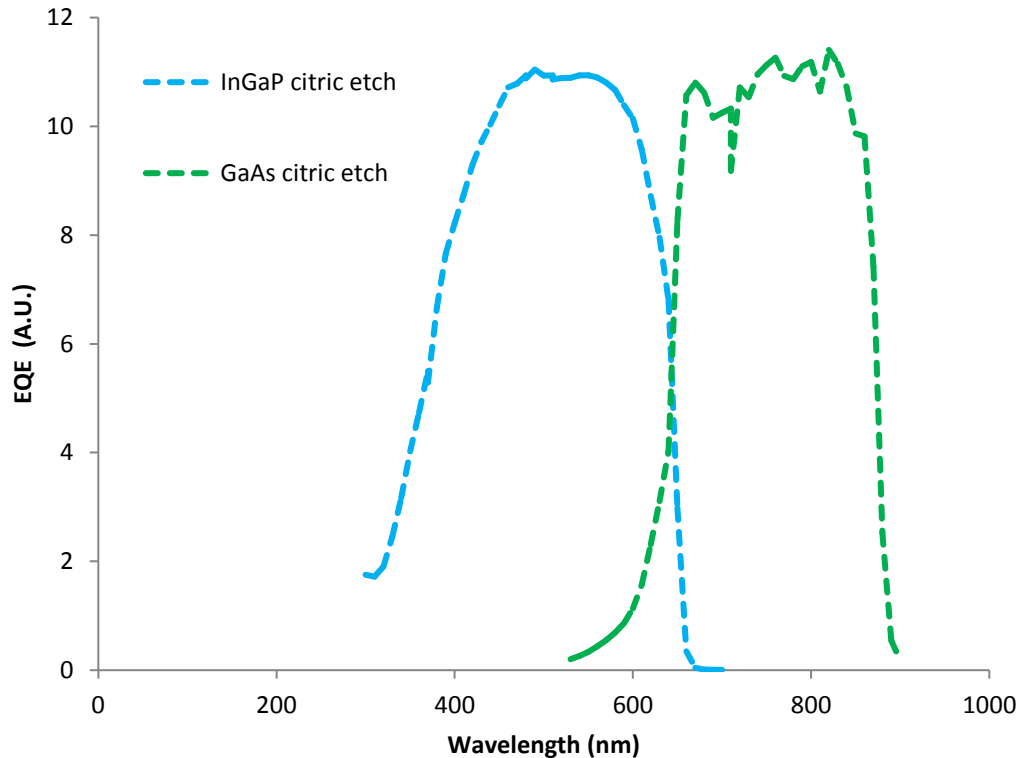
Smaller cells optimize efficiency at higher concentrations



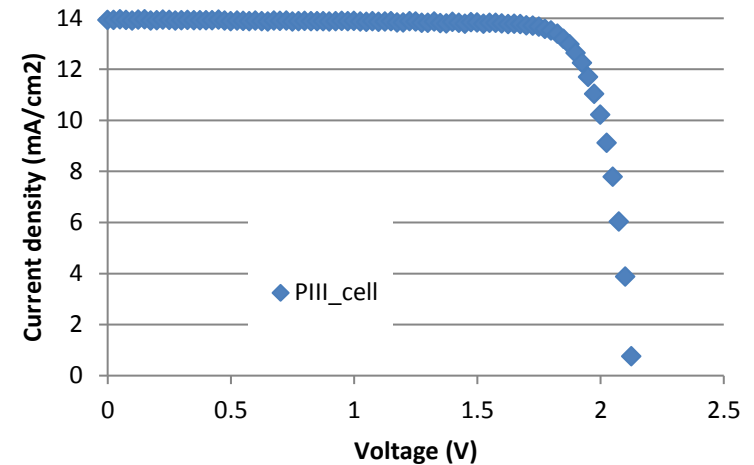


Prototype III had a great performance with only 6um of thickness bonded onto silicon

EQE for InGaP/GaAs cell

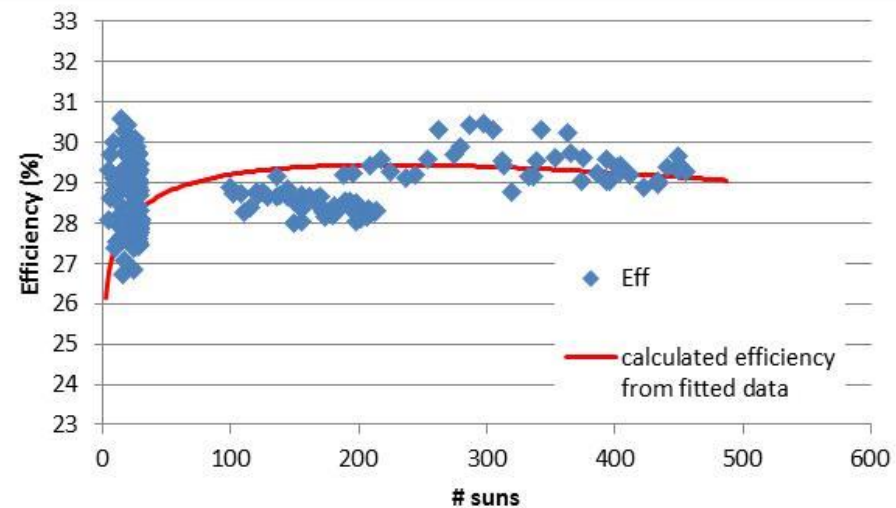
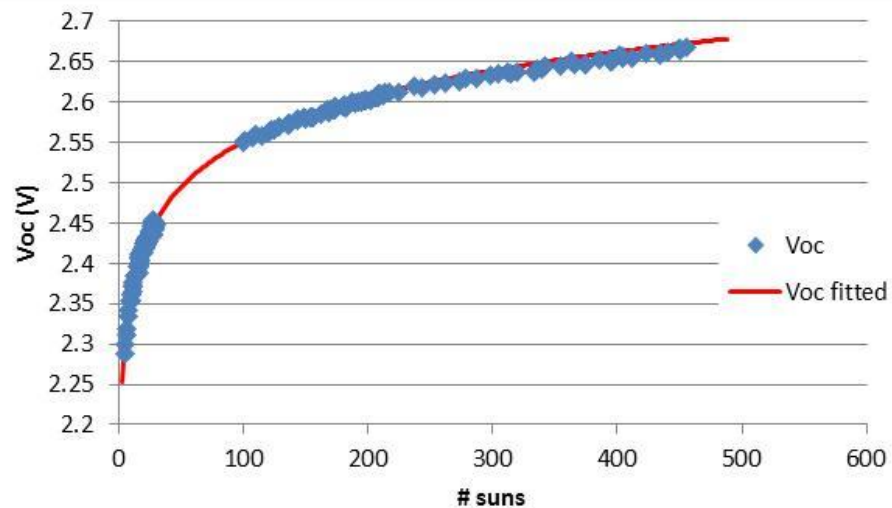
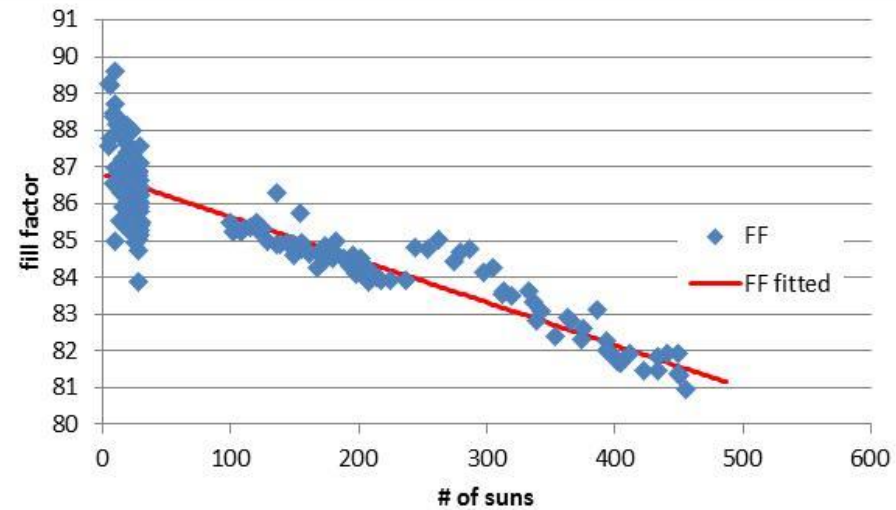
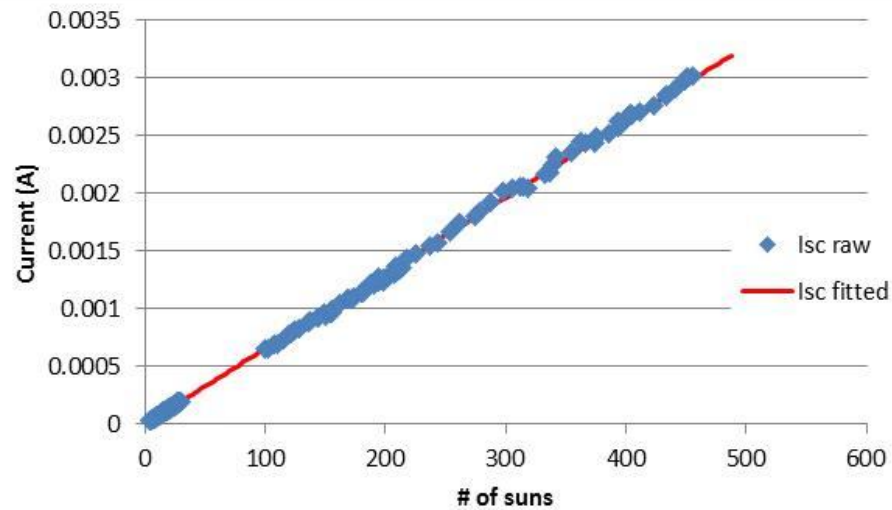


PIII_cell



- PIII InGaP/GaAs cell efficiency: 26%

Concentration tests (flash tester) PIII InGaP/GaAs cell at 22°C



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Thin Film PV



Improves material quality

Crystalline silicon PV



Improves functionality
(flexible films)

Concentrated PV



Lowers price
Improves performance

This is an exciting time for solar!

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If you want to do more about solar
[NMSEA - New Mexico Solar Energy Association](http://www.nmsea.org/)
www.nmsea.org/

Thank you for your attention
Questions?